A framework for modeling bioimpedance measurements of nonhomogeneous tissues: a theoretical and simulation study

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Abstract. **Objective:** Bioimpedance technology is experiencing an increased use to assess health in a wide range of new consumer, research and clinical applications. However, the interaction between tissues producing bioimpedance data is often unclear. **Methods:** This work provides a novel theoretical framework to model bioimpedance measurements of nonhomogeneous tissues. We consider five case studies to validate the usefulness of our approach against finite element model (FEM) simulations. **Results:** Theoretical and FEM-simulated apparent resistance and reactance data were in good agreement, with a maximum relative errors < 4% and < 8%, respectively. **Conclusion:** The biophysics-driven framework developed provides compact analytical expressions to model nonhomogeneous bioimpedance measurements including multiple tissues with arbitrary shape and electrical properties. This work provides a new perspective to interpret nonhomogeneous bioimpedance measurements using **series**, **parallel**, and **series-parallel** circuit-like topology equivalents. **Significance:** Our framework is a new tool to better understand and describe complex nonhomogeneous biological measurements as, for example, cardiac, brain and respiratory applications using (non)invasive electrodes.

**Keywords:** electrical bioimpedance, nonhomogeneous tissue, finite element model, forward model.
1. Introduction

Bioimpedance technology can detect cancerous lymph nodes (Hong et al. 2020), diagnose a broad range of disorders (Ibrahim et al. 2005, Haas et al. 2012, Cumming et al. 2014, Zamani et al. 2018, Parke et al. 2015, Rutkove & Sanchez 2018) and evaluate treatment outcomes (Lorenzo et al. 2020). The working principle consists of applying a nonstimulating, nonionizing electrical current through tissue using two dedicated current electrodes and recording the voltage generated with a second pair of dedicated electrodes. From the amplitude and time-lag relationship between the current and voltage signals, impedance data is measured (Grimnes & Martinsen 2011).

The impedance reflects the exogenous electrical conduction property of tissues. These electrical properties measure how strongly tissue resists (or conducts) alternating electric current and how capable is the tissue to store electric charge within itself (Schwan & Foster 1989). They are determined by the electrical properties, namely the conductivity $\sigma$ (S m$^{-1}$) and the relative permittivity $\varepsilon_r$ (dimensionless), relative to the permittivity of the vacuum $\varepsilon_0$ (F m$^{-1}$). In skeletal muscle for example, these two fundamental electrical properties change with disease progression (Sanchez et al. 2020).

As illustrated in Figure 1, the electrical current applied for the biompedance measurement might flow through more than one tissue or fluid, each with different electrical properties. Formally, these different tissues and fluids will contribute to the apparent impedance $Z \in \mathbb{C}$ (Ohms) measured as follows (Geselowitz 1971)

$$Z = \int_{\Omega} \left( \frac{J_I(r)}{\sigma(r) + \tau \omega_k \varepsilon_r(r) \varepsilon_0} \right) \cdot J_V(r) \, dr,$$

where $\Omega \in \mathbb{R}^3$ is the domain with coordinate system $r := (x, y, z)$, $J_I, J_V \in \mathbb{C}$ (m$^{-2}$) are the local current density vectors found swapping the injection of electrical current between the current $I$ and voltage $V$ electrodes, respectively, $\omega_k \in \mathbb{R}$ (rad s$^{-1}$) is the (angular) frequency of electrical current, and $\tau := \sqrt{-1}$ is the imaginary unit (dimensionless). The above expression shows that depending on (1) the electrodes, (2) the domain and (3) the electrical properties of the tissues.
Within the domain, the apparent impedance might represent an amalgam of different tissues. For example, in a localized surface electrical impedance myography measurements, data are influenced by skin and subcutaneous fat tissues at the recording site (Kwon, Malik, Rutkove & Sanchez 2019). If the electrodes are placed farther apart on a limb for example, then the impedance will become dependent on the geometry of the domain (Bachasson et al. 2021). Figure 2 summarizes the complexity of the different existing bioimpedance models according to the electrodes, domain and tissue.

Figure 2. Summary of forward bioimpedance models. The assumptions of the framework developed in this study are italicized.

In this paper we develop a framework capable of describing nonhomogeneous impedance measurement containing multiple tissues with different electrical properties, electrodes’ positioning, and arbitrary domain shapes. The paper is organized as follows. We first define a nonhomogeneous model using mathematical notation in Section 2. Then nonhomogeneous impedance of series, parallel, series-parallel circuit-like topologies are analytically modeled in half space in Section 3, 4, 5, respectively. Section 6 extends the series-parallel circuit-like topology model to full space. Section 7 describes the simulation settings and the simulation results in Section 8 confirm the usefulness of the novel framework presented. Finally, the contribution is discussed in Section 9 and summarized in the form of conclusions in Section 10.


In this paper we model nonhomogeneous tissue as a semi-infinite space $\Lambda^- \in \mathbb{R}^3$ and infinite space $\Lambda \in \mathbb{R}^3$ containing $M \in \mathbb{N}_{\geq 1}$ domains. Then, we study bioimpedance measurements in $\{\Lambda^-,\Lambda\}$ considering 3 different nonhomogeneous “electrical circuit-like” topologies shown in Figure 3 according to how the current flows from one domain to another: series, parallel and series-parallel, formally defined next. Let’s start by considering $M$ non-overlapping domains $\Omega_i \in \{\Lambda^-,\Lambda\}$ with $i \in \{1,2,\cdots,M\}$, where each domain has different electrical properties
(these electrical properties are defined in the next section) satisfying \( \bigcup _{1 \leq i \leq M} \Omega _i = \{ \Lambda _-, \Lambda \} \).
We next define \( \partial \Omega _i \) as the outer surface boundary of \( \Omega _i \). Then, \( \forall i, j \in \{ 1, 2, \cdots , M \} \) and \( i \neq j \), two domains are non-overlapping if \( \Omega _i \cap \Omega _j = \partial \Omega _k \) where \( k \in \{ i, j \} \) or \( \Omega _i \cap \Omega _j = \emptyset \). Note that in the case where \( \Omega _i \cap \Omega _j = \partial \Omega _k \), the electrical current can propagate from \( \Omega _i \) to \( \Omega _j \) through the boundary \( \Omega _k \) directly, whereas in the case where \( \Omega _i \cap \Omega _j = \emptyset \) the current must propagate through another domain first.

Figure 3. Schematic representing nonhomogeneous tissue as a semi-infinite domain \( \Lambda _- \in \mathbb{R}^3 \) and infinite domain \( \Lambda \in \mathbb{R}^3 \) with (A) series (denoted by the superscript \( S \)), (B) parallel (denoted by the superscript \( P \)) and (C) series-parallel (denoted by the superscript \( SP \)) electrical circuit-like topology containing \( M = 5 \) subdomains \( \Omega _i \) with boundary \( \partial \Omega _i \) and \( i \in \{ 1, \cdots , M \} \).

We define \( \Omega _i \) neighbor to \( \Omega _j \) as \( i \mid j \) when \( \Omega _i \cap \Omega _j = \partial \Omega _k \). The neighbor definition satisfies the principle of reciprocity, that is to say, \( \Omega _i \) is neighbor to \( \Omega _j \), and vice versa. Then, we can define a neighbor set \( N(\Omega _i) := \{ \Omega _j \mid (i \mid j) \} \) for domain \( \Omega _i \) as the set containing all neighbors of \( \Omega _i \). Moreover, we define the cardinality of neighbor set \( |N(\Omega _i)| \) as the number of all elements in \( N(\Omega _i) \). Henceforth, superscripts + and − of \( N(\Omega _i) \) refer to the neighbors outside and inside \( \Omega _i \), respectively, so that \( |N(\Omega _i)| = |N^+(\Omega _i)| + |N^-(\Omega _i)| \). To describe the elements in \( N^\pm(\Omega _i) \), we use the notation \( i^\pm \in \{ j \mid \Omega _j \in N^\pm(\Omega _i) \} \). Then, the outer/inner neighbor relation of \( \Omega _i \) is \( \Omega _i^\pm \in N^\pm(\Omega _i) \). Finally, using these notations, we can define series, parallel and series-parallel topology as shown in Table 3. Note that series and parallel topology are two specific cases of a more general series-parallel topology.

Next we develop in Sections 3, 4 and 5 a forward analytical framework modeling tetrapolar impedance measurements of nonhomogeneous tissue considering a series, parallel and series-parallel circuit-like topologies, respectively.

3. Electrical impedance model in half space with series circuit-like topology

The coordinate \( \mathbf{r} := (x, y, z) \) defines a position in \( \Lambda ^S \), where the superscript \( S \) denotes a series circuit-like topology. To determine the electrical potential distribution within \( \Lambda ^S \) (see Figure 4 A), we consider a sinusoidal electrical current of amplitude \( I \in \mathbb{R} \) at (angular) frequency \( \omega _k \in \mathbb{R}_{>0} \) (rad s\(^{-1} \)), generated by point-like source \( S \) at \( \mathbf{r}_S := (x_S, y_S, 0) \) with current sink at infinity. In other words, this assumption reduces to considering only one (positive) current being applied to the model responsible of generating the distribution of electrical potential. The voltage recording point-like electrode \( E \) at \( \mathbf{r}_E := (x_E, y_E, 0) \) is then placed on \( \partial \Omega _1 : z = 0 \) to record the electrical potential with reference zero potential at infinity. Henceforth, we have following assumptions: (1) the current source and voltage recording electrodes are
Table 1. Definitions of series, parallel, series-parallel circuit-like topology for nonhomogeneous tissue with $i,i^\pm \in \{1,2,3,\cdots,M\}$.

<table>
<thead>
<tr>
<th>Topology</th>
<th>Definition</th>
<th>Property</th>
</tr>
</thead>
<tbody>
<tr>
<td>Series</td>
<td>$</td>
<td>N(\Omega_1)</td>
</tr>
<tr>
<td></td>
<td>$\Omega_i \in N^-(\Omega_{i-1})$, where $i \neq 1$, $\Omega_i \in N^-(\Omega_{i-1})$, where $i \neq 1$,</td>
<td></td>
</tr>
<tr>
<td>Parallel</td>
<td>$</td>
<td>N(\Omega_1)</td>
</tr>
<tr>
<td>Series-parallel</td>
<td>$</td>
<td>N^+(\Omega_1)</td>
</tr>
</tbody>
</table>

Figure 4. (A) Schematic illustrating a nonhomogeneous tissue modeled as series circuit-like topology in half space $\Lambda^S$ (A) and its mirrored image in $\mathbb{R}^3$ (B). There are $M$ nested domains $\Omega_i$ in $\Lambda^S$ where $i \in \{1,2,3,\cdots,M\}$. Surface $\partial \Omega_i$ is the outer boundary of $\Omega_i$ with isotropic admittivity is $\gamma_i$. Surface $\partial \Omega_1$ is a plane $(x,y,0)$ while other surface $\partial \Omega_i (i \neq 1)$ have arbitrary surfaces. A point source $S$ at $r_S := (x_S, y_S, 0)$ on $\partial \Omega_1$ generates sinusoidal current. Another point $E$ at $r_E := (x_E, y_E, 0)$ is a potential recording electrode on $\partial \Omega_1$. Point $Q_i (i > 1)$ is at position $r_{Q_i} := (x_{Q_i}, y_{Q_i}, z_{Q_i})$ on $\partial \Omega_i$, and $n_i$ is the outward normal vector of $\partial \Omega_i$ at $Q_i$. $R_{SE}$ is the distance between $S$ and $E$. (B) The half-space model $\Lambda^S$ is mirrored with respect to plane $\partial \Omega_1$ and forms the mirrored full space $\mathbb{R}^3$. All mirrored elements in (B) are overlined to distinguish form their nonmirrored counterparts shown in (A). (C) Schematic illustrating a tetrapolar electrical impedance measurement on $\partial \Omega_1$ for $\Lambda^S$. The current source (+) and sink (−) electrodes are $S_\pm$ and the high (+) and low (−) voltage measuring electrodes are $E_\pm$ placed on $\partial \Omega_1$. 

dimensionless; (2), the domains have isotropic electrical properties; (3), there are no free charges in the model; and (4), the current cannot flow outside the model.
3.1. Governing equation

From Maxwell equations in quasistationary regime (Maxwell 1873), the governing equation of the electrical potential distribution \( U^{S}(r) \in \mathbb{C}(V) \) is the generalized Poisson equation

\[
\nabla \cdot \left( \gamma^{S}(r) \nabla U^{S}(r) \right) = -I \delta (r - r_{S}),
\]

where \( \gamma^{S} \in \mathbb{C}(\text{S m}^{-1}) \) is the nonhomogeneous admittivity property and \( \delta (r) \) is the Dirac delta function. To solve (1), we first need to describe the admittivity distribution in \( \Lambda^{S} \). The isotropic admittivity in domain \( \Omega_{i} \) is defined as \( \gamma := \sigma_{i} + \tau \omega_{k} \epsilon_{i} \), \( \sigma_{i} \in \mathbb{R}_{>0} \) and \( \epsilon_{i} \in \mathbb{R}_{>0} \) are the conductivity (S m\(^{-1}\)) and the absolute permittivity (F m\(^{-1}\)) properties in \( \Omega_{i} \) at frequency \( \omega_{k} \), respectively. Due to the nested structure of subdomains in \( \Lambda^{S} \), shown in Figure 4 A, the admittivity distribution \( \gamma^{S}(r) \) can be explicitly described from series topology in Table 3 as

\[
\gamma^{S}(r) := \gamma_{1} + \sum_{i=2}^{M} (\gamma_{i} - \gamma_{i-1}) H(r + n_{i}),
\]

where function \( H(r) \) is the Heaviside unit step function, vector \( n_{i} \) is the outward normal vector of \( \partial \Omega_{i} \) at point \( Q_{i} \), the latter an arbitrary point on \( \partial \Omega_{i} \). Applying the half-maximum convention of \( H(r) \), one can find admittivity \( (\gamma_{i} + \gamma_{i-1})/2 \) on \( \partial \Omega_{i} \) with \( i \neq 1 \) from (2). Then, the Dirac delta function \( \delta (r) \) can be expressed as the divergence of Heaviside unit step function \( \nabla H(r_{Q_{i}}) = \delta (r_{Q_{i}}) n_{i} \), where \( r_{Q_{i}} := (x_{Q_{i}}, y_{Q_{i}}, z_{Q_{i}}) \) is the position at \( Q_{i} \). Then we can rewrite (1) as

\[
\nabla^{2} U^{S}(r) = -\frac{I \delta (r - r_{S})}{\gamma^{S}(r)} - 2 \sum_{i=2}^{M} \Gamma_{i-1|i} \delta (\partial \Omega_{i}) \frac{\partial U^{S}(r)}{\partial n_{i}} \cdot n_{i},
\]

where \( r \neq r_{S} \), \( \Gamma_{i|i} \in \mathbb{C} \) (dimensionless) is the reflection coefficient of the boundary between subdomains \( \Omega_{i} \) and \( \Omega_{j} \) defined as \( \Gamma_{i|i} := (\gamma_{i} - \gamma_{j})/(\gamma_{i} + \gamma_{j}) \) with \( i, j \in \{1, 2, \ldots , M\} \) and \( i \neq j \).

The boundary condition is \( \partial U^{S}(r)/\partial z \big|_{\partial \Omega_{1}} = 0 \). To satisfy this boundary condition, we apply the method of images charges to (3). As shown in Figure 4 B, the half space model \( \Lambda^{S} \) is mirrored with respect to the plane \( z = 0 \) to construct a full space model in \( \mathbb{R}^{3} \). Considering the image reflection term, the governing equation becomes

\[
\nabla^{2} U^{S}(r) = -\frac{2I \delta (r - r_{S})}{\gamma^{S}(r)} - 2 \sum_{i=2}^{M} \Gamma_{i-1|i} \left[ \delta (\partial \Omega_{i}) \frac{\partial U^{S}(r)}{\partial n_{i}} \cdot n_{i} + \delta (\partial \Omega_{i}) \frac{\partial U^{S}(r)}{\partial \bar{n}_{i}} \cdot \bar{n}_{i} \right],
\]

where all overlined notations are mirrored elements from their original counterparts with respect to the plane \( \partial \Omega_{1} \).
3.2. Electrical potential distribution

To obtain the expression of potential $U^S(\mathbf{r})$ analytically, we simplify (4) with the method of Green’s function as in (Cohl & Tohline 1999), namely

$$
\begin{align*}
U^S(\mathbf{r}) &= U_0(\mathbf{r}) + \sum_{i=2}^{M} U^S_{\Omega_i}(\mathbf{r}) \\
U_0(\mathbf{r}) &= \frac{I}{2\pi \gamma |\mathbf{r} - \mathbf{r}_S|} \\
U^S_{\Omega_i}(\mathbf{r}) &= \frac{\Gamma_{i-1|i}}{2\pi} \left[ \iint_{\partial \Omega_i} \frac{\partial U^S_{\Omega_i}(\mathbf{Q}_i)}{\partial \mathbf{n}_i} \cdot \mathbf{n}_i \frac{d(\partial \Omega_i)}{|\mathbf{r} - \mathbf{r}_{\mathbf{Q}_i}|} + \iint_{\partial \Omega_i} \frac{\partial U^S_{\Omega_i}(\mathbf{Q}_i)}{\partial \mathbf{n}_i} \cdot \mathbf{n}_i \frac{d(\partial \Omega_i)}{|\mathbf{r} - \mathbf{r}_{\mathbf{Q}_i}|} \right],
\end{align*}
$$

(5)

where operator $\cdot \mathbf{r}$ is the $L_2$ norm, $d(\partial \Omega_i)$ and $d(\partial \Omega_i)$ represent the area of the micro-elements $\partial \Omega_i$ and $\partial \Omega_i$ at Q$_i$ and Q$_i$, respectively. We next solve (5) using an iterative approximation. Following the same rationale as in (Wazwaz 2007), the $p$th-order approximated (denoted by $\tilde{\cdot}$) electrical potential distribution with series topology $\tilde{U}^{S(p)}(\mathbf{r}) \in \mathbb{C}$ is defined as

$$
\begin{align*}
\tilde{U}^{S(p)}(\mathbf{r}) &= U_0(\mathbf{r}) + \sum_{i=2}^{M} \tilde{U}^{S(p)}_{\Omega_i}(\mathbf{r}) \\
\tilde{U}^{S(0)}(\mathbf{r}) &= U_0(\mathbf{r}) \\
\tilde{U}^{S(p)}_{\Omega_i}(\mathbf{r}) &= \frac{\Gamma_{i-1|i}}{2\pi} \left[ \iint_{\partial \Omega_i} \frac{\partial \tilde{U}^{S(p-1)}_{\Omega_i}(\mathbf{Q}_i)}{\partial \mathbf{n}_i} \cdot \mathbf{n}_i \frac{d(\partial \Omega_i)}{|\mathbf{r} - \mathbf{r}_{\mathbf{Q}_i}|} + \iint_{\partial \Omega_i} \frac{\partial \tilde{U}^{S(p-1)}_{\Omega_i}(\mathbf{Q}_i)}{\partial \mathbf{n}_i} \cdot \mathbf{n}_i \frac{d(\partial \Omega_i)}{|\mathbf{r} - \mathbf{r}_{\mathbf{Q}_i}|} \right],
\end{align*}
$$

(6)

where $p \in \mathbb{N}_{>0}$ is the order of approximation. According to the definition of reflection coefficient, we have $|\Gamma_{i|i}| \leq 1$. Then the analytical expression of potential distribution gives $U^S(\mathbf{r}) = \lim_{p \to \infty} \tilde{U}^{S(p)}(\mathbf{r})$.

The electrical potential is recorded with electrode $E$ at $\mathbf{r}_E := (x_E, y_E, 0)$ (see Figure 4 A). Then, we can simplify the third expression in (6) based on the symmetry of image charges (see Figure 4 B) as

$$
\tilde{U}^{S(p)}_{\Omega_i}(\mathbf{r}_E) = \frac{\Gamma_{i-1|i}}{\pi} \iint_{\partial \Omega_i} \frac{\partial \tilde{U}^{S(p-1)}_{\Omega_i}(\mathbf{Q}_i)}{\partial \mathbf{n}_i} \cdot \mathbf{n}_i \frac{d(\partial \Omega_i)}{|\mathbf{r}_E - \mathbf{r}_{\mathbf{Q}_i}|}. $$

The 1st-order approximated electrical potential can be deduced from (6) as

$$
\tilde{U}^{S(1)}(\mathbf{r}_E) = \frac{I}{2\pi \gamma_i} \left( \frac{1}{R_{SE}} + 2 \sum_{i=2}^{M} K_{\Omega_i} \Gamma_{i-1|i} \right),
$$

(7)

where

$$
K_{\Omega_i} := -\frac{1}{2\pi} \iint_{\partial \Omega_i} \frac{\partial}{\partial \mathbf{n}_i} \frac{\partial |\mathbf{r}_{\mathbf{Q}_i} - \mathbf{r}_S|}{\partial \mathbf{n}_i} \cdot \mathbf{n}_i \frac{d(\partial \Omega_i)}{|\mathbf{r}_{\mathbf{Q}_i} - \mathbf{r}_S|^2 |\mathbf{r}_E - \mathbf{r}_{\mathbf{Q}_i}|}
$$

is a geometrical constant (m$^{-1}$) determined by the shape and position of $\Omega_i$, and distance $R_{SE}$ (m) between electrode $S$ and $E$. 


3.3. Apparent electrical impedance

Consider the tetrapolar impedance model shown in Figure 4 where $S_+$ and $S_-$ are the current source (+) and sink (−) electrodes (i.e., the potential generated by both the source and sink current electrodes), respectively, and where $E_+$ and $E_-$ are the high (+) and low (−) voltage recording electrodes, respectively. The 1st-order potential difference $\Delta \tilde{U}^{S(1)} \in \mathbb{C} (\mathrm{V})$ is defined from (7) as

$$
\Delta \tilde{U}^{S(1)} := \left( \tilde{U}^{S(1)}_{++} - \tilde{U}^{S(1)}_{+-} \right) - \left( \tilde{U}^{S(1)}_{-+} - \tilde{U}^{S(1)}_{--} \right),
$$

where $\tilde{U}^{S(1)}_{++}$ and $\tilde{U}^{S(1)}_{+-}$ are the 1st-order approximation of the electrical potential generated by current source electrode $S_+$ and recorded by the high potential $E_+$ electrode, respectively, $\tilde{U}^{S(1)}_{-+}$ and $\tilde{U}^{S(1)}_{--}$ are the first order approximation of the electrical potential generated by current source electrode $S_-$ and recorded by the high potential $E_+$ and low potential $E_-$ electrode, respectively. According to (7), we have

$$
\Delta \tilde{U}^{S(1)} = \frac{I}{2\pi \gamma_1} \left( G + 2 \sum_{i=2}^{M} K_i \Gamma_{i-1|i} \right),
$$

where the geometrical constant $G := 1/R_{++} - 1/R_{+-} + 1/R_{-+} - 1/R_{--}$ (m$^{-1}$) is determined by the position of the current and voltage electrodes, $R_{wv}$ (m) is the distance between electrode $S_v$ and $E_w$ with $w,v \in \{+,−\}$, the geometrical coefficient $K_i := K_{i+} - K_{i−} + K_{−i} - K_{+i}$ (m$^{-1}$) is determined by the shape and position of domain $\Omega_i$ with

$$
K_{i+}^{R_{wv}} := -\frac{1}{2\pi} \int_{\partial \Omega_i} \frac{\partial R_{Q,S_v}(r_{Q_i})}{\partial n_i} \cdot n_i \frac{d(\partial \Omega_i)}{R_{Q,S_v}(r_{Q_i})R_{Q,E_w}(r_{Q_i})} (\mathrm{m}^{-1}),
$$

where $R_{Q,S_v}$ and $R_{Q,E_w}$ (m) are the distance between point $Q_i$ and electrodes $S_v$ and $E_w$, respectively. From (8), the 1st-order approximated apparent electrical impedance $Z^{S(1)} \in \mathbb{C}$ (Ohm) is expressed as

$$
Z^{S(1)} := R^{S(1)} + \tau X^{S(1)} = \frac{\Delta \tilde{U}^{S(1)}}{I} = \frac{1}{2\pi \gamma_1} \left( G + 2 \sum_{i=2}^{M} K_i \Gamma_{i-1|i} \right),
$$

where $R^{S(1)}, X^{S(1)} \in \mathbb{R}$ (Ohm) are the 1st-order approximated apparent resistance and reactance, respectively.

3.4. Apparent electrical impedance sensitivity to changes in tissue electrical properties

Next, we study the apparent impedance sensitivity to changes in intrinsic electrical properties within the model. For this, we define $\Delta \gamma := \Delta \sigma_i + \tau \omega \Delta \varepsilon_i$ in (9) and $|\Delta \gamma| \ll |\gamma|$. Then based on 1st-order Taylor series for $\Delta \gamma/\gamma$ in (9), one can approximate the apparent electrical
impedance sensitivity $\Delta Z^{S(1)}/Z^{S(1)}$ to relative change of admittance $\Delta \gamma_i/\gamma_i$, as follows

$$\Delta Z^{S(1)}/Z^{S(1)} \approx \begin{cases} 
-\frac{\Delta \gamma_i}{\gamma_i} \left(1 - \frac{2\sigma_{i+1}}{Z^{S(1)}} \right) & \text{if } i = 1 \\
-\frac{\Delta \gamma_i}{\gamma_i} \frac{2\sigma_{i-1}}{Z^{S(1)}} & \text{if } i = M \\
-\frac{\Delta \gamma_i}{\gamma_i} \left(\frac{2\sigma_{i-1}}{Z^{S(1)}} + \frac{2\sigma_{i+1}}{Z^{S(1)}}\right) & \text{else},
\end{cases}$$

where $\sigma_{j|i} := K_i \gamma_i/\left(\pi \gamma_i (\gamma_i + \gamma_j)^2\right)$ (Ohm).

3.5. Case study 1

Here we consider the case study of a nonhomogeneous tissue consisting of $M = 3$ domains where $\Omega_2$ and $\Omega_3$ are modeled as a concentric spherical shell-kernel (see Figure 5 A). The 1st-order approximated electrical potential distribution $\bar{U}^{S(1)}(r_E)$ recorded on $\partial \Omega_1$ can be expressed using (7) as follows

$$K_{\Omega_i} = \frac{1}{b_i} \sum_{n=0}^{\infty} \frac{2n}{2n+1} \left(\frac{b_i^2}{R_{SC_i} R_{EC_i}}\right)^{n+1} P_n(\cos \theta_i),$$

where $i \in \{2,3\}$, $\theta_i$ (rad) is the angle between line segment $|SC_i|$ and the line segment $|EC_i|$, $\cos \theta_i = (R_{SC_i}^2 + R_{EC_i}^2 - R_{SE}^2)/(2R_{SC_i} R_{EC_i})$, $b_i$ (m) is the radius of $\Omega_i$, $R_{PC_i}$ (m) is the distance
between point $P \in \{S, E\}$ and $C_i$, and $P_n(x)$ are Legendre polynomials. We refer the reader to Lemma 1 in the Supplementary Information for further details regarding the mathematical derivation of the spherical geometrical coefficient in (11).

Figure 5 B illustrates the placement of current $S_\pm$ and voltage $E_\pm$ electrodes for impedance measurement. Then, the 1st-order approximated electrical potential difference, apparent electrical impedance and apparent impedance sensitivity can be evaluated using (8), (9) and (10), respectively, with
\[
K_i = \sum_{n=0}^{\infty} G_{i,n},
\]
and
\[
G_{i,n} := \frac{2n b_i^{2n+1}}{2n+1} \left( \frac{P_n(\cos \theta_{i+1})}{R_{i,S_+}^{n+1} R_{i,E_+}^n} - \frac{P_n(\cos \theta_{i-1})}{R_{i,S_-}^{n+1} R_{i,E_-}^n} \right),
\]
in which $\theta_{iw}$ (rad) with $w,v \in \{+, -\}$ is the angle between line segment $|C_i S_v|$ and $|C_i E_w|$, $R_{i,S_v}$ and $R_{i,E_w}$ (m) are the distances between $C_i$ and $S_v$ and $E_w$, respectively.

If we consider the electrodes are linearly aligned on $\partial \Omega_1$ and satisfy $|C_i S_+| = |C_i S_-|$ as illustrated in Figure 5 C, then we can simplify geometrical constant $G$ in (8) and (9) as follows
\[
G = \frac{2B}{A(A + B)},
\]
where $A$ and $B$ (m) are the interelectrode distances between current-voltage and voltage-voltage electrodes, respectively. We can also simplify $G_{i,n}$ in (12) as
\[
G_{i,n} = \frac{4n b_i^{2n+1}}{2n+1} \left( \frac{4}{L_i} \right)^{n+1} \left( \frac{P_n \left( \frac{4l_i + t}{L_i} \right)}{L_i} - \frac{P_n \left( \frac{4l_i - t}{L_i} \right)}{L_i} \right),
\]
and $G_{i,0} = 0$, where $L_i := \sqrt{(2A + B)^2 + 4l_i^2} \sqrt{B^2 + 4l_i^2}$ and $t := 2AB + B^2$, $l_i$ is the distance (m) between $C_i$ and the center of line segment $|E_i E_{i-1}|$.

3.6. Case study 2

Here we consider the case study of a nonhomogeneous layered tissue consisting of $M = 3$ domains and where $\Omega_1$, $\Omega_2$ and $\Omega_3$ are stacked (see Figure 6 A). The model is defined by $\Omega_1 : 0 < z < h_1$, $\Omega_2 : h_1 < z < h_1 + h_2$ and $\Omega_3 : z > h_1 + h_2$ with planar boundaries $\partial \Omega_1 := (x, y, 0)$, $\partial \Omega_2 := (x, y, h_1)$ and $\partial \Omega_3 := (x, y, h_2)$, respectively. Distances $h_1$ and $h_2$ (m) represent the thickness of tissues $\Omega_1$ and $\Omega_2$, respectively. The 1st-order approximated electrical potential distribution $\tilde{U}^{S(1)}(\mathbf{r}_E)$ on $\partial \Omega_1$ can be expressed using (7), where
\[
K_{\Omega_i} = \frac{1}{\sqrt{R_{SE}^2 + 4N_i^2}},
\]
where $i \in \{2, 3\}$, $N_i := \sum_{j=1}^{i-1} h_j$ (m) is the distance from $\partial \Omega_i$ to $\partial \Omega_1$ and $R_{SE}$ (m) is the distance between $S$ and $E$. We refer the reader to Lemma 2 in the Supplementary Information.
for further details regarding the mathematical derivation of planar geometrical coefficient in (14).

In this case, the recorded electrical potential difference, apparent electrical impedance and apparent impedance sensitivity in Figure 6 B can be evaluated using (8), (9) and (10) with

$$K_i = \frac{1}{\sqrt{R_{S_+E_+}^2 + 4N_i^2}} - \frac{1}{\sqrt{R_{S_-E_-}^2 + 4N_i^2}} + \frac{1}{\sqrt{R_{S_-E_+}^2 + 4N_i^2}} - \frac{1}{\sqrt{R_{S_+E_-}^2 + 4N_i^2}},$$

(15)

where \(R_{mn} (m)\) is the distance between \(m \in \{S_+, S_-\}\) and \(n \in \{E_+, E_-\}\).

If we consider the four electrodes linearly aligned (see Figure 6 C), then the geometrical constant (15) simplifies to

$$K_i = \frac{2}{\sqrt{A^2 + 4N_i^2}} - \frac{2}{\sqrt{(A+B)^2 + 4N_i^2}},$$

with \(A\) and \(B\) (m) the distances between current and voltage electrodes and inner voltage electrodes, respectively, and \(G\) is given in (13).

4. Electrical impedance model in half space with parallel circuit-like topology

In this section we consider a nonhomogeneous model \(\Lambda^P_\infty \in \mathbb{R}^3\) consisting of circuit-like parallel topology domains. The model assumptions are the same as in Section 3.

4.1. Governing equation

As in Section 3, the governing equation is

$$\nabla \cdot (\gamma^P(r) \nabla U^P(r)) = -I \delta(r - r_S).$$

(16)
where $\gamma \in \mathbb{C} (S \text{ m}^{-1})$ and $U \in \mathbb{C} (V)$ are the nonhomogeneous admittivity and the electrical potential in $\Lambda^p$, respectively. The subdomains are arranged as shown in Figure 7 A. According to Table 3, the admittivity distribution $\gamma (r)$ can be explicitly expressed as

$$\gamma (r) := \gamma_1 + \sum_{i=2}^{M} (\gamma_i - \gamma_1) H(r + n_i).$$

Following the same rationale as in Section 3, we can apply the method of images charges to (16), namely

$$\nabla^2 U (r) = -\frac{2I \delta (r - r_S)}{\gamma (r)} - 2 \sum_{i=2}^{M} \Gamma_{1i} \left[ \delta (\partial \Omega_i) \frac{\partial U (r)}{\partial n_i} \cdot n_i + \delta (\partial \overline{\Omega}_i) \frac{\partial U (r)}{\partial \overline{n}_i} \cdot \overline{n}_i \right],$$

where $r \neq r_S$ and $\Gamma_{1i}$ is the reflection coefficient.

4.2. Electrical potential distribution

Similar to (6), we can introduce a $p$th-order approximated electrical potential distribution $\tilde{U}^{(p)}(r) \in \mathbb{C} (V)$ from (18), i.e.,

$$\begin{cases}
\tilde{U}^{(p)}(r) := U_0 (r) + \sum_{i=2}^{M} \tilde{U}^{(p)}_{\Omega_i} (r) \\
\tilde{U}^{(0)}(r) := U_0 (r) \\
\tilde{U}^{(p)}_{\Omega_i} (r) := \frac{\Gamma_{1i}}{2\pi} \left[ \int_{\partial \Omega_i} \frac{\partial U^{(p-1)} (r_{Q_i})}{\partial n_i} \cdot n_i \frac{d(\partial \Omega_i)}{\partial r_{Q_i}} + \int_{\partial \overline{\Omega}_i} \frac{\partial U^{(p-1)} (r_{Q_i})}{\partial \overline{n}_i} \cdot \overline{n}_i \frac{d(\partial \overline{\Omega}_i)}{\partial r_{Q_i}} \right],
\end{cases}$$

where $U (r) = \lim_{p \to \infty} \tilde{U}^{(p)} (r)$. 

Figure 7. (A) Schematic illustrating a nonhomogeneous tissue modeled as parallel circuit-like topology in half space $\Lambda^p$. There are $M$ domains $\Omega_i$ with $i \in \{1, 2, 3, \ldots, M\}$ and isotropic admittivity $\gamma_i$ in $\Lambda^p$, where $M - 1$ domains $\Omega_i$ and $i \neq 1$ are intruded in $\Omega_1$. Surface $\partial \Omega_i := (x, y, 0)$ is the planar boundary of $\Omega_1$, while $\partial \Omega_i$ are outer boundary of $\Omega_i$ with an arbitrary surface. A point-like source $S$ at $r_S := (x_S, y_S, 0)$ on $\partial \Omega_1$ generates electrical current. Another point-like electrode $E$ at $r_E := (x_E, y_E, 0)$ is a potential recording electrode on $\partial \Omega_1$. Point $Q_i$ ($i \neq 1$) has coordinates $r_{Q_i} := (x_{Q_i}, y_{Q_i}, z_{Q_i})$ on $\partial \Omega_i$, and $n_i$ is the outward normal vector of $\partial \Omega_i$ at $Q_i$. Length $R_{SE}$ is the distance between electrode $S$ and $E$. (B) Schematic illustrating a surface tetrapolar electrical impedance measurement. The current source (+) and sink (−) electrodes are $S_{±}$ and the high (+) and low (−) voltage measuring electrodes are $E_{±}$ placed on $\partial \Omega_1$, respectively.
The electrical potential is recorded with electrode $E$ at $r_E := (x_E, y_E, 0)$ (see Figure 7 A). Then, we can simplify (19) based on the symmetry of the image model with respect to $\partial \Omega_1$ (see Figure 4 B). The 1st-order approximated electrical potential at $r_E$ is

$$
\tilde{U}^{P(1)}(r_E) = \frac{I}{2\pi \gamma_1} \left( \frac{1}{R_{SE}} + 2 \sum_{i=2}^{M} K_{\Omega} \Gamma_{1|i} \right).
$$

(20)

### 4.3. Apparent electrical impedance

We consider a tetrapolar impedance model as shown in Figure 7 B. Similar to (8), the measured potential difference $\Delta \tilde{U}^{P(1)} \in \mathbb{C}$ (V) can be obtained from (20), viz.,

$$
\Delta \tilde{U}^{P(1)} = \frac{I}{2\pi \gamma_1} \left( G + 2 \sum_{i=2}^{M} K_i \Gamma_{1|i} \right).
$$

(21)

Finally, the 1st-order apparent electrical impedance $Z^{P(1)} \in \mathbb{C}$ (Ohm) is

$$
Z^{P(1)} := R^{P(1)} + \tau X^{P(1)} = \frac{\Delta \tilde{U}^{P(1)}}{I} = \frac{1}{2\pi \gamma_1} \left( G + 2 \sum_{i=2}^{M} K_i \Gamma_{1|i} \right),
$$

(22)

where $R^{P(1)}, X^{P(1)} \in \mathbb{R}$ (Ohm) are the 1st-order approximated apparent resistance and reactance, respectively.

### 4.4. Apparent electrical impedance sensitivity to changes in tissue electrical properties

Following the same rationale as in Section 3.4, we can find apparent electrical impedance sensitivity $\Delta Z^{P(1)}/Z^{P(1)}$ from (22), namely

$$
\frac{\Delta Z^{P(1)}}{Z^{P(1)}} \approx \begin{cases} 
- \frac{\Delta \gamma}{\gamma} \left( 1 - \sum_{k=2}^{M} \frac{2 \sigma_{ik}}{Z^{P(1)}} \right) & \text{if } i = 1 \\
- \frac{\Delta \gamma}{\gamma} \frac{2 \sigma_{1i}}{Z^{P(1)}} & \text{else}
\end{cases}
$$

(23)

### 4.5. Case study 3

Here we consider the case study of a nonhomogeneous tissue with $M = 3$ domains where $\Omega_{\{2,3\}}$ are spheres surrounded by tissue $\Omega_1$ (see Figure 8 A). Domain $\Omega_{\{2,3\}}$ is centered at $C_{\{2,3\}}$ with radius $b_{\{2,3\}}$ (m), boundary $\partial \Omega_{\{2,3\}}$. Angle $\theta_{\{2,3\}}$ (rad) is between line segment $|SC_{\{2,3\}}|$ and $|EC_{\{2,3\}}|$ with source $S$ and electrode $E$ on $\partial \Omega_1 : (x, y, 0)$. The 1st-order approximated electrical potential distribution $\tilde{U}^{SP(1)}(r_E)$ can be expressed using (20) in $\Lambda_\text{p}$, where the geometrical coefficient $K_{\Omega}$ is the same as (11).

Figure 8 B shows the current $S_\pm$ and voltage $E_\pm$ electrodes for impedance measurement positioned on $\partial \Omega_1$. The electrical potential difference, apparent electrical impedance and apparent impedance sensitivity can be calculated using (21), (22) and (23), where the geometrical coefficients $K_{\{2,3\}}$ are the same as (12). If the voltage and current electrodes
As in Section 3, the governing equation is
\[ \nabla \cdot \left( \gamma^{SP}(\mathbf{r}) \nabla U^{SP}(\mathbf{r}) \right) = -I \delta(\mathbf{r} - \mathbf{r}_S). \] (24)

where \( \gamma^{SP} \in \mathbb{C} \ (S \text{ m}^{-1}) \) and \( U^{SP} \in \mathbb{C} \ (V) \) are the nonhomogeneous admittivity and the electrical potential in \( \Lambda^{SP} \), respectively. According to the property of series-parallel circuit-like topology listed in Table 3, we can explicitly express the admittivity distribution \( \gamma^{SP}(\mathbf{r}) \)
Based on the principle of image charges as in (25), the planar surface \( \partial \Omega_1 := (x, y, 0) \) is the boundary of \( \Omega_1 \), whereas \( \partial \Omega_i \) are outer boundary of \( \Omega_i \). Domains \( \Omega_{i+} \in N^+(\Omega_i) \) are the outer/inner neighbors of \( \Omega_i \), where \( i^+ \in \{1, 2, 3, \ldots, i-1, i+1, \ldots, M\} \).

Following the same rationale as in (6), the \( p \)-th order approximated electrical potential distribution \( \tilde{U}^{SP(p)}(\mathbf{r}) \in \mathbb{C}(V) \) is defined

\[
\begin{align*}
\tilde{U}^{SP(p)}(\mathbf{r}) & := U_0(\mathbf{r}) + \sum_{i=2}^{M} \tilde{U}^{SP(p)}(\Omega_i)(\mathbf{r}) \\
\tilde{U}^{SP(0)}(\mathbf{r}) & := U_0(\mathbf{r}) \\
\tilde{U}^{SP(p)}(\Omega_i)(\mathbf{r}) & := \frac{\Gamma_{i+}}{2\pi} \left[ \iint_{\partial \Omega_i} \frac{\partial \tilde{U}^{SP(p-1)}(r_{Q_i})}{\partial \mathbf{n}_i} \cdot \mathbf{n}_i \frac{d(\partial \Omega_i)}{|r-r_{Q_i}|} \right] + \iiint_{\Omega_i} \frac{\partial \tilde{U}^{SP(p-1)}(r_{Q_i})}{\partial \mathbf{n}_i} \cdot \mathbf{n}_i \frac{d(\partial \Omega_i)}{|r-r_{Q_i}|}
\end{align*}
\]

5.2. Electrical potential distribution

Following the same rationale as in (6), the \( p \)-th order approximated electrical potential distribution \( \tilde{U}^{SP(p)}(\mathbf{r}) \in \mathbb{C}(V) \) is defined

\[
\begin{align*}
\tilde{U}^{SP(p)}(\mathbf{r}) & := U_0(\mathbf{r}) + \sum_{i=2}^{M} \tilde{U}^{SP(p)}(\Omega_i)(\mathbf{r}) \\
\tilde{U}^{SP(0)}(\mathbf{r}) & := U_0(\mathbf{r}) \\
\tilde{U}^{SP(p)}(\Omega_i)(\mathbf{r}) & := \frac{\Gamma_{i+}}{2\pi} \left[ \iint_{\partial \Omega_i} \frac{\partial \tilde{U}^{SP(p-1)}(r_{Q_i})}{\partial \mathbf{n}_i} \cdot \mathbf{n}_i \frac{d(\partial \Omega_i)}{|r-r_{Q_i}|} \right] + \iiint_{\Omega_i} \frac{\partial \tilde{U}^{SP(p-1)}(r_{Q_i})}{\partial \mathbf{n}_i} \cdot \mathbf{n}_i \frac{d(\partial \Omega_i)}{|r-r_{Q_i}|}
\end{align*}
\]
where \( U^{SP}(r) = \lim_{r \to \infty} \tilde{U}^{SP(p)}(r) \). Considering a voltage recording electrode \( E \) on \( \partial \Omega_1 \) (see Figure 9 A), we can simplify the 1st-order approximated electrical potential \( \tilde{U}^{SP(1)}(r_E) \) as

\[
\tilde{U}^{SP(1)}(r_E) = \frac{I}{2\pi \gamma_1} \left( \frac{1}{R_{SE}} + \sum_{i=2}^{M} K_{\Omega_i} \Gamma_{\gamma^+|i} \right).
\]  

(28)

5.3. Apparent electrical impedance

We consider the surface tetrapolar impedance measurement shown in Figure 9 B. Similar to (8), the 1st-order approximated potential difference \( \Delta \tilde{U}^{SP(1)} \in \mathbb{C} \) (V) is

\[
\Delta \tilde{U}^{SP(1)} = \frac{I}{2\pi \gamma_1} \left( G + \sum_{i=2}^{M} K_{\gamma_i} \Gamma_{\gamma^+|i} \right).
\]  

(29)

Finally, the 1st-order approximated apparent electrical impedance \( Z^{SP(1)} \in \mathbb{C} \) (Ohm) from (29) is

\[
Z^{SP(1)} := R^{SP(1)} + \tau X^{SP(1)} = \frac{\Delta \tilde{U}^{SP(1)}}{I} = \frac{1}{2\pi \gamma_1} \left( G + \sum_{i=2}^{M} K_{\gamma_i} \Gamma_{\gamma^+|i} \right),
\]  

(30)

where \( R^{SP(1)}, X^{SP(1)} \in \mathbb{R} \) (Ohm) are the 1st-order approximated apparent resistance and reactance, respectively.

5.4. Apparent electrical impedance sensitivity to changes in tissue electrical properties

Following the same rationale as in Section 3.4, we can find apparent electrical impedance sensitivity \( \Delta Z^{SP(1)}/Z^{SP(1)} \) from (30), namely

\[
\frac{\Delta Z^{SP(1)}}{Z^{SP(1)}} \approx \begin{cases} \\
-\frac{\Delta \gamma}{\gamma} \left[ 1 - \sum_{i \in \{ j \mid \Omega_j \in N^-(\Omega_i) \}} \frac{\sigma_{\gamma^+|i}}{Z} \right] & \text{if } i = 1 \\
-\frac{\Delta \gamma}{\gamma} \frac{\sigma_{\gamma^+|i}}{Z} & \text{if } i = M \\
-\frac{\Delta \gamma}{\gamma} \left[ \frac{\sigma_{\gamma^+|i}}{Z} + \sum_{i \in \{ j \mid \Omega_j \in N^-(\Omega_i) \}} \frac{\sigma_{\gamma^+|i}}{Z} \right] & \text{else.}
\end{cases}
\]  

(31)

5.5. Case study 4

Here we consider the case study of a nonhomogeneous model with \( M = 4 \) domains consisting of two spherical volumes \( \Omega_2 \) and \( \Omega_3 \) within a two-layered tissue \( \Omega_1 \) and \( \Omega_4 \). The model is defined with \( \Omega_1 := 0 < z < h_1 \) and \( \Omega_2 : \{ z > h_1 \} \) and \( \Omega_3 : \{ z > h_1 \} \) with boundary \( \partial \Omega_1 := \{ x, y, 0 \} \) and \( \partial \Omega_4 := \{ x, y, h_1 \} \), respectively, and where \( h_1 \) (m) is the thickness of \( \Omega_1 \). Domains \( \Omega_{\{2,3\}} \) in \( \Omega_4 \) are modeled as spherical volumes with radii \( h_{\{2,3\}} \) (m) and boundaries \( \partial \Omega_{\{2,3\}} \) (see Figure 10 A). Angles \( \theta_{\{2,3\}} \) (rad) are defined as the angles between the line segments \(|SC_{\{2,3\}}|\) and \(|EC_{\{2,3\}}|\) with current source \( S \) and voltage electrode \( E \) on \( \partial \Omega_1 \).
Figure 10. Schematic of case study 4. (A) Nonhomogeneous model $\Lambda^{SP} \in \mathbb{R}^3$ with series-parallel circuit-like topology consisting of two-layered domains $\Omega_i$ and $\Omega_4$ and two spherical volumes $\Omega_2$ and $\Omega_3$ in $\Omega_4$. The admittance and boundary of $\Omega_i$ are $\gamma_i$ and $\partial \Omega_i$, $i \in \{1, 2, 3, 4\}$, with $\partial \Omega_1 := (x, y, 0)$ and $\partial \Omega_4 := (x, y, h_1)$. The spherical domains $\Omega_{(2,3)}$ are centered at $C_{(2,3)}$ with radii $b_{(2,3)}$. A point-like source $S$ at $r_S := (x_S, y_S, 0)$ generates electrical current. A point-like electrode $E$ at $r_E := (x_E, x_E, 0)$ measures the electrical potential. Length $K_{SE}$ is the distance between $S$ and $E$, angle $\theta_{(2,3)}$ is the angle between the line segment $|SC_{(2,3)}|$ and $|EC_{(2,3)}|$. (B) Schematic illustrating a surface tetrapolar electrical impedance measurement. The current source (+) and sink (−) electrodes are $S_2$ and the high (+) and low (−) voltage measuring electrodes are $E_{\pm}$. (C) Tetrapolar electrical impedance measurement for case study 4 with linearly aligned current source electrodes $S_2$ and measuring voltage $E_{\pm}$ electrodes. The center $C_{(2,3)}$ satisfies $|C_{(2,3)}S_+| = |C_{(2,3)}S_-|$. The distance from $C_{(2,3)}$ to line segment $|E_+E_-|$ is $l_{(2,3)}$, the angle between $l_{(2,3)}$ and $x$-axis is $\theta_{C_{(2,3)}}$. The distance between current and voltage electrodes is $A$, whereas the distance between voltage electrodes is $B$.

The 1st-order approximated electrical potential recorded can determined using (28) using the geometrical coefficients $K_{\Omega_{(2,3)}}$ and $K_{\Omega_4}$ defined in (11) and (14), respectively. The 1st-order approximated electrical potential difference, apparent electrical impedance and apparent impedance sensitivity shown in Figure 10 B can be evaluated using (29), (30) and (31) where $K_{(2,3)}$ and $K_4$ are the same as in (12) and (15). If the electrodes are linearly aligned on $\partial \Omega_1$ and $|C_{(2,3)}S_+| = |C_{(2,3)}S_-|$ (see Figure 10 C), then the distances $l_{(2,3)}$ (m) are defined from $C_{(2,3)}$ to the line segment $|E_+E_-|$ and the angles $\theta_{C_{(2,3)}}$ (rad) are the angles between $l_{(2,3)}$ and the $x$-axis. $A$ and $B$ (m) are the distance between current and voltage electrodes and between voltage electrodes, respectively. Finally, the same simplifications can be made for $K_{(2,3)}$ as in (12), $K_4$ as in (15), and $G$ as in (13).


In this section we extend the framework in Section 5 to full space $\Lambda^{SP} \in \mathbb{R}^3$ (see Figure 11 A). This generalization represents the model when the electrodes are not on the surface of the tissue but surrounded by tissue as for example when using penetrating electrodes. The model assumptions in Section 3 that apply in full space are (1) to (3).
be directly deduced from (32), namely

\[ S_{\Omega} \]

We consider a point-like source distribution in \( \Lambda \). Following the same rationale as in (6), one can obtain the potential distribution where \( \gamma \). As in Section 3, the governing equations in \( \Lambda^{\text{SP}} \) is

\[ \nabla \cdot \left( \gamma^{\text{SP}}(r) \nabla U^{\text{SP}}(r) \right) = -I \delta(r - r_S). \]  

(32)

where \( \gamma^{\text{SP}} \in \mathbb{C} \) (S m\(^{-1}\)) and \( U^{\text{SP}} \in \mathbb{C} \) (V) are the nonhomogeneous admittivity and the electrical potential in \( \Lambda^{\text{SP}} \), respectively. The model \( \Lambda^{\text{SP}} \) contains domains \( \Omega_1^{'} \) and \( \Omega_i \), \( i \neq 1 \), as illustrated in Figure 11 A, where \( \Omega_1^{'} \cup (\bigcup_{2 \leq i \leq M} \Omega_i) = \Lambda^{\text{SP}} \). Of note, the admittivity distribution in \( \Lambda^{\text{SP}} \) shares the same definition as that in \( \Lambda^{\text{SP}} \) in (25), i.e., \( \gamma^{\text{SP}}(r) = \gamma^{\text{SP}}(r) \). We consider a point-like source \( S' \) at \( r_{S'} := (x_{S'}, y_{S'}, z_{S'}) \) in \( \Omega_1^{'} \). The governing equation can be directly deduced from (32), namely

\[ \nabla^2 U^{\text{SP}}(r) = -I \frac{\delta(r - r_{S'})}{\gamma^{\text{SP}}} - 2 \sum_{i=2}^{M} \Gamma_{i+|i|} \delta(\partial\Omega_i) \frac{\partial U^{\text{SP}}(r)}{\partial n_i} \cdot n_i, \]  

(33)

where \( r \neq r_{S'} \) and reflection coefficient \( \Gamma_{i+|i|} \) has the same definition as in Section 5.

6.2. Electrical potential distribution

Following the same rationale as in (6), one can obtain the \( p \)th-order approximated electrical potential distribution \( \tilde{U}^{\text{SP}(p)}(r) \in \mathbb{C}(V) \) in \( \Lambda^{\text{SP}} \) as

\[
\begin{align*}
\tilde{U}^{\text{SP}}(r) &:= \sum_{i=2}^{M} \tilde{U}_{\Omega_i}^{\text{SP}}(r), \\
\tilde{U}_{\Omega_2}^{\text{SP}}(r) &:= \frac{\Gamma_{i+|i|}}{2\pi} \int_{\partial\Omega_2} \frac{d\tilde{U}^{\text{SP}(p-1)}(r)}{dr} \cdot n_i, \\
\end{align*}
\]  

(34)
where $U^{SP}(r) = \lim_{n \to \infty} \tilde{U}^{SP}(r)$. A point-like electrode $E'$ at $r_{E'} = (x_{E'},{y}_{E'},z_{E'})$ measures the electrical potential (see Figure 11 A). Then, the 1st-order electrical potential $\tilde{U}^{SP(1)}(r_{E'})$ can be simplified from (34) as

$$
\tilde{U}^{SP(1)}(r_{E'}) = \frac{I}{4\pi \gamma_1} \left( \frac{1}{R_{S'E'}} + \sum_{i=2}^{M} K_{E} \Gamma_{i+|i|} \right),
$$

where $R_{S'E'}$ (m) is the distance between source $S'$ and electrode $E'$, geometrical coefficient $K_{E}$ (m$^{-1}$) maintains the same definition as $K_{\Omega}$ in (7) replacing $S$, $E$ with $S'$, $E'$.

### 6.3. Apparent impedance measurement

We consider a tetrapolar electrical impedance measurement shown in Figure 11 B. The electrodes of current source (+) and sink (−) are $S_{\pm}$ and the measuring electrodes of high (+) and low (−) potential are $E_{\pm}$. Similar to (8), we can deduce the 1st-order approximated potential difference $\Delta \tilde{U}^{SP(1)} \in \mathbb{C}$ (V) as

$$
\Delta \tilde{U}^{SP(1)} = \frac{I}{4\pi \gamma_1} \left( G' + \sum_{i=2}^{M} K_{E} \Gamma_{i+|i|} \right),
$$

where geometrical constant $G' := 1/R_{TT} - 1/R_{TT}' + 1/R_{TT} - 1/R_{TT}'$ (m$^{-1}$), in which $R_{TT'}$ (m) is the distance between electrode $S_{T'}$ and $E_{T'}$ with $w, v \in \{+, -\}$, geometrical coefficient $K_{i}$ (m$^{-1}$) maintains the same definition as $K_{i}$ in (8) replacing $S, E$ with $S', E'$. Finally, the 1st-order approximated apparent electrical impedance $Z^{SP(1)} \in \mathbb{C}$ (Ohm) from (36) gives

$$
Z^{SP(1)} := R^{SP(1)} + \tau \chi^{SP(1)} = \frac{\Delta \tilde{U}^{SP(1)}}{I} = \left( G' + \sum_{i=2}^{M} K_{E} \Gamma_{i+|i|} \right),
$$

where $R^{SP(1)}, \chi^{SP(1)} \in \mathbb{R}$ (Ohm) are the 1st-order approximated apparent resistance and reactance, respectively.

### 6.4. Apparent electrical impedance sensitivity to changes in tissue electrical properties

Following the same rationale as in Section 3.4, we can find apparent electrical impedance sensitivity $\Delta Z^{SP(1)}/Z^{SP(1)}$ from (37), namely

$$
\frac{\Delta Z^{SP(1)}}{Z^{SP(1)}} \approx \left\{ \begin{array}{ll}
-\frac{\Delta \gamma_{i}}{\gamma_{i}} \left[ 1 - \sum_{i \in \{j|\Omega_{j} \notin N'(\Omega_{i})\}} \frac{\sigma_{ji}}{Z^{SP(1)}} \right] & \text{if } i = 1 \\
-\frac{\Delta \gamma_{i}}{\gamma_{i}} \frac{\sigma_{+i}}{Z^{SP(1)}} & \text{if } i = M \\
-\frac{\Delta \gamma_{i}}{\gamma_{i}} \left[ \frac{\sigma_{ji}}{Z} + \sum_{i \in \{j|\Omega_{j} \notin N'(\Omega_{i})\}} \frac{\sigma_{ji}}{Z^{SP(1)}} \right] & \text{else},
\end{array} \right.
$$

where $\sigma_{ji}$ (Ohm) maintains the same definition as $\sigma_{ji}$ in (10) replacing the geometrical coefficient $K_{i}$ in half space with $K_{i}'$ in full space.
A framework for modeling bioimpedance measurements of nonhomogeneous tissues

Table 2. Finite element model simulation settings shown in Figure 12.

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<th>Symbol</th>
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<th>Case study 3</th>
<th>Case study 4 &amp; 5</th>
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6.5. Case study 5

Here we consider the case study of nonhomogeneous tissue with $M = 4$ domains consisting of two spherical volumes $\Omega_2$ and $\Omega_3$ within two half-space tissue $\Omega_1'$ and $\Omega_4$. Of note, all the geometrical configurations of case study 5 are modeled the same as case study 4 (see Figure 10) except $\Omega_1$ in $\Lambda_{SP}$ is extended to $\Omega_1' := z > h_1$ in $\Lambda_{SP}$. The source (+) and sink (−) current source and high (+) and low (−) potential recording electrodes are $S'_\pm$ and $E'_\pm$, respectively. The 1st-order approximation of the electrical potential $\tilde{U}_{SP}(1)$, electrical potential difference $\Delta \tilde{U}_{SP}(1)$, apparent electrical impedance $Z'_{SP}(1)$ and apparent impedance sensitivity $\Delta Z'_{SP}(1)/Z'_{SP}(1)$ can be formulated by (35), (36), (37) and (38), respectively, where the geometrical parameters $K'_{\Omega_{2,3}}$, $K'_{\Omega_4}$, $G'$, $K'_4$ and $K'_4$ keep the same expressions as in (11), (12), (13), (14) and (15) replacing $S, E$ with $S', E'$.

7. Materials and methods

We confirm the accuracy of our theoretical framework through numerical (MATLAB, The Mathworks, Natick, MA, USA) and finite element model (FEM, Comsol Multiphysics, Comsol, Inc., Burlington, MA, USA) simulations. The model simulation settings are summarized in Table 2. In the model, geometrical parameters $l_2$, $l_3$, $\theta_{C_2}$, $h_1$, $h_2$ and electrical property parameters $\sigma_2$, $\sigma_3$, $\epsilon_{r_2}$, $\epsilon_{r_3}$ are variables in our simulations. Additional FEM simulation parameters are provided next.

7.1. Finite element model simulations

Figure 12 illustrates the three-dimensional FEM models developed to validate our theoretical framework. For the simulations of case study 1 (Figure 12 A) and case study 3 (Figure
12 B), the domain $\Omega_1$ is modeled as a cuboid with dimensions width $\times$ length $\times$ height $140 \times 140 \times 100$ mm. For the simulations of case study 2 (Figure 12 C), $\Omega_1$ and $\Omega_2$ are modeled as cuboids with dimensions $140 \times 140 \times h_1$ mm and $140 \times 140 \times h_2$ mm, whereas $\Omega_3$ has dimensions $140 \times 140 \times (100 - h_1)$ mm. For the simulations of case study 4 (Figure 12 D) and case study 5 (Figure 12 E), the domain $\Omega_4$ is modeled as a cuboid with dimensions width $\times$ length $\times$ height $140 \times 140 \times h_1$ mm and $140 \times 140 \times (100 + h_1)$ mm, respectively. The dimensions of the domain satisfy simulation results are not affected by the domain boundary, in other words, the domain can be considered half space and full space. Adaptive mesh is used to ensure simulation accuracy by having a finer spatial mesh resolution near the electrodes and boundary between domains, while being a coarser mesh spatial resolution elsewhere. The minimum mesh element size is $10^{-4}$ mm, the maximum element growth rate is 1.2 and the curvature factor is 0.2. The total elements for the model of cases 1, 2, 3 are 192,108; 1,654,653 and 206,945, respectively, whereas for case 4 and 5 are 1,174,848 and 353,545, respectively. BiCGStab solver is used to run the simulations and the relative tolerance is set as 0.001.

7.2. Apparent electrical impedance

The 1st-order approximated apparent impedance is computed in Matlab for series, parallel, series-parallel circuit-like topology in half space and full space using (9), (22), (30) and (37). Since the 1st-order approximated electrical potential depends on the reflection coefficient between domains with different admittivity properties, we evaluate the accuracy of our predictions to changes in the conductivity and (relative) permittivity properties defined as $\delta_{\sigma_i} := (\sigma_i - \sigma_1)/\sigma_1$ and $\delta_{\varepsilon_i} := (\varepsilon_i - \varepsilon_1)/\varepsilon_1$, respectively. Finally, the relative error between the theoretical and FEM simulated apparent resistance and reactance results is calculated as $e_R := (R_{\text{Theory}} - R_{\text{FEM}})/R_{\text{FEM}}$ and $e_X := (X_{\text{Theory}} - X_{\text{FEM}})/X_{\text{FEM}}$, respectively.

8. Simulation results

8.1. Apparent electrical impedance of series topology

Figures 13 (A, B and C) and 14 (A and B) compare the 1st-order approximated numerical and FEM-simulated apparent impedance for case study 1 and case study 2, respectively. Figures 13 (D, E, F and G) and 14 (C, D, E and F) plot the relative error distribution of apparent resistance and reactance values varying the conductivity and relative permittivity properties of tissue from -50% to 50% while keeping the rest of model parameters constant.

Overall, theoretical and FEM-simulated results are in good agreement with varying depth of spherical center from 6 to 14 mm in case study 1 (Figure 13 A); the 1st-order approximation also being able to detect spherical changes shown in Figure 13 B and C. In addition, impedance results for case study 2 shown in Figure 14 A, B are in good agreement changing the tissue thickness from 1 to 5 mm. The accuracy of the 1st-order approximated apparent resistance (Figure 13 D, F) and reactance (Figure 13 E, G) predictions for case study
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Figure 12. Three-dimensional views of the finite element models (FEM) developed to validate the accuracy of our theoretical impedance framework of nonhomogeneous tissue considering: (A), case study 1 in half space with series circuit-like topology; (B), case study 3 in half space with parallel circuit-like topology; (C), case study 2 in half space with series circuit-like topology; case study 4 and case study 5 with series-parallel circuit-like topology in half space (D) and full space (E). The current source (+) and sink (−) electrodes are $S\pm, S'\pm$ and the high (+) and low (−) potential recording electrodes $E\pm, E'\pm$ measure the apparent electrical impedance. We refer the reader to Table 2 for additional model setting parameters.

1 are $< 1.5\%$ and $< 5\%$, respectively. For case study 2, the maximum error is $< 2\%$ for resistance (Figure 14 C and E) and $< 4\%$ for reactance (Figure 14 D and F).

8.2. Apparent electrical impedance of parallel topology

Figure 15 compares the 1st-order approximated numerical and FEM-simulated apparent impedance for case study 3. The results show the theoretical framework can accurately model changes in position and size of the spherical domain (Figure 15 A, B, C). The maximum error of apparent resistance and reactance to changes in conductivity and relative permittivity properties are $< 0.1\%$ and $< 0.5\%$, respectively (Figure 15 D, E). Interestingly, if the dimension of the spherical volume and the relative distance from the spherical domain to current sources and voltage electrodes are kept constant (see Figure 15 C), then changing the azimuth angle of the spherical volume has no influence on the apparent impedance.
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Figure 13. Analytical and FEM-simulated impedance results of case study 1 (see Figure 5 C and Figure 12 A). Theoretical (solid line) and FEM-simulated (dotted line) resistance and reactance with $l_{(2,3)} = [6, 14]$ mm, $b_2 = 4$ mm and $b_3 = 3$ mm (A); $b_2 = [2, 6]$ mm, $l_{(2,3)} = 7$ mm and $b_3 = 1$ mm (B); $b_3 = [1.5]$ mm, $l_{(2,3)} = 7$ mm and $b_2 = 6$ mm (C). Additional simulation setting parameters: $\sigma_1 = 1 \text{ S m}^{-1}$, $\varepsilon_r_2 = 1 \times 10^5$ (dimensionless), $\sigma_2 = 1.1 \text{ S m}^{-1}$, $\varepsilon_r_3 = 1.1 \times 10^5$ (dimensionless), $\sigma_3 = 0.9 \text{ S m}^{-1}$, $\varepsilon_r_3 = 0.9 \times 10^5$ (dimensionless). (D, E) Relative resistance and reactance errors changing the admittivity of domain $\Omega_2$ (i.e., $\delta_\sigma_2$ and $\delta_\varepsilon_2$) with $\sigma_3 = 1.1 \text{ S m}^{-1}$, $\varepsilon_r_3 = 0.9 \times 10^5$ (dimensionless). (F, G) Relative resistance and reactance errors changing the admittivity of domain $\Omega_3$ (i.e, $\delta_\sigma_3$, $\delta_\varepsilon_3$) with $\sigma_2 = 1.1 \text{ S m}^{-1}$, $\varepsilon_r_2 = 0.9 \times 10^5$ (dimensionless). Additional simulation setting parameters: $\sigma_1 = 1 \text{ S m}^{-1}$, $\varepsilon_r_2 = 1 \times 10^5$ (dimensionless), $l_{(2,3)} = 9$ mm, $b_2 = 6$ mm, $b_3 = 5$ mm.
Figure 14. Analytical and FEM-simulated impedance results of case study 2 (see Figure 6 C and Figure 12 C). Theoretical (solid line) and FEM-simulated (dotted line) resistance and reactance with \( h_1 = [1,5] \) mm, \( h_2 = 1 \) mm (A); \( h_1 = 1 \) mm, \( h_2 = [1,5] \) mm (B). Additional simulation parameters: \( \sigma_1 = 1 \text{s} \cdot \text{m}^{-1}, \varepsilon_{r1} = 1 \times 10^5 \) (dimensionless), \( \sigma_2 = 1.1 \text{s} \cdot \text{m}^{-1}, \varepsilon_{r2} = 1.1 \times 10^5 \) (dimensionless), \( \sigma_3 = 0.9 \text{s} \cdot \text{m}^{-1}, \varepsilon_{r3} = 0.9 \times 10^5 \) (dimensionless). (C, D) Relative resistance and reactance errors changing the admittivity of domain \( \Omega_2 \) (i.e., \( \delta_\sigma_2, \delta_\varepsilon_2 \)) with \( \sigma_3 = 1.1 \text{s} \cdot \text{m}^{-1}, \varepsilon_{r3} = 0.9 \times 10^5 \) (dimensionless). (E, F) Relative resistance and reactance errors changing the admittivity of domain \( \Omega_3 \) (i.e., \( \delta_\sigma_3, \delta_\varepsilon_3 \)) with \( \sigma_2 = 1.1 \text{s} \cdot \text{m}^{-1}, \varepsilon_{r2} = 0.9 \times 10^5 \) (dimensionless). Additional simulation parameters: \( \sigma_1 = 1 \text{s} \cdot \text{m}^{-1}, \varepsilon_{r1} = 1 \times 10^5 \) (dimensionless), \( h_1 = 2 \) mm, \( h_2 = 2 \) mm.
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Figure 15. Analytical and FEM-simulated impedance results of case study 3 (see Figure 8 C and Figure 12 B). Theoretical (solid line) and FEM-simulated (dotted line) resistance and reactance with \( l_2 = [6, 14] \) mm, \( l_3 = 7 \) mm, \( b_{[2,3]} = 4 \) mm, \( \theta_{C_{[2,3]}} = 45 \) degrees (A); \( b_2 = [2, 6] \) mm, \( b_3 = 4 \) mm, \( l_{[2,3]} = 7 \) mm, \( \theta_{C_{2}} = 45 \) degrees (B); \( \theta_{C_{2}} = [40^\circ, 60^\circ] \), \( \delta_{C_{3}} = 45^\circ \), \( l_{[2,3]} = 7 \) mm, \( b_{[2,3]} = 4 \) mm (C). Additional simulation setting parameters: \( \sigma_1 = 1 \text{ S m}^{-1}, \varepsilon_{r2} = 1 \times 10^5 \) (dimensionless), \( \sigma_2 = 1.1 \text{ S m}^{-1}, \varepsilon_{r2} = 1.1 \times 10^5 \) (dimensionless), \( \sigma_3 = 0.9 \text{ S m}^{-1}, \varepsilon_{r3} = 0.9 \times 10^5 \) (dimensionless). (D, E) Relative resistance and reactance errors changing the admittivity of domain \( \Omega_2 \) (i.e., \( \delta_{\sigma_2}, \delta_{\varepsilon_{r2}} \)) with \( \sigma_1 = 1 \text{ S m}^{-1}, \varepsilon_{r2} = 1 \times 10^5 \) (dimensionless), \( \sigma_3 = 1.1 \text{ S m}^{-1}, \varepsilon_{r3} = 0.9 \times 10^5 \) (dimensionless), \( l_{[2,3]} = 7 \) mm, \( b_2 = 4 \) mm, \( \theta_{C_{[2,3]}} = 45^\circ \).

8.3. Apparent electrical impedance of series-parallel topology

Figures 16 and 17 compare the 1st-order approximated numerical and FEM-simulated apparent impedance for case study 4 in half space and case study 5 in full space, respectively. In both half and full space, there is good agreement with varying thickness (Figure 16 A and Figure 17 A), dimensions of the spherical domains (Figure 16 B and Figure 17 B), and relative distance to the spherical center (Figure 16 C and Figure 17 C). Figure 16 D and Figure 17 D reveal that the azimuth angle of the spherical volume does not contribute to the apparent impedance. The maximum errors changing the conductivity and relative permittivity
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Figure 16. Analytical and FEM-simulated impedance results of case study 4 (see Figure 10 C and Figure 12 D). Theoretical (solid line) and FEM-simulated (dotted line) resistance and reactance with \( h_1 = [1.5 \text{ mm}], l_{[2,3]} = 8 \text{ mm}, b_{[2,3]} = 2 \text{ mm}, \theta_C^{[2,3]} = 70^\circ \) (A); \( b_2 = [2, 6] \text{ mm}, b_3 = 4 \text{ mm}, l_{[2,3]} = 10 \text{ mm}, \theta_C^{[2,3]} = 45^\circ \) (B); \( h_2 = [6, 14] \text{ mm}, l_3 = 7 \text{ mm}, h_1 = 1 \text{ mm}, b_{[2,3]} = 3 \text{ mm}, \theta_C^{[2,3]} = 45^\circ \) (C); \( \theta_C = [40^\circ, 60^\circ], \theta_C^3 = 45^\circ, l_{[2,3]} = 7 \text{ mm}, b_{[2,3]} = 3 \text{ mm} \) (D). Additional simulation setting parameters: \( r_1 = 1 \text{ S m}^{-1}, \epsilon_2 = 1 \times 10^5 \) (dimensionless), \( \sigma_2 = 1.1 \text{ S m}^{-1}, \epsilon_2 = 1.1 \times 10^5 \) (dimensionless), \( \sigma_3 = 0.9 \text{ S m}^{-1}, \epsilon_3 = 0.9 \times 10^5 \) (dimensionless), \( \sigma_4 = 0.95 \text{ S m}^{-1}, \epsilon_4 = 1.05 \times 10^5 \) (dimensionless). Relative resistance and reactance errors changing the admittivity of domain \( \Omega_{[2,3]} \) (i.e., \( \delta_{\sigma_{2,3}} = \delta_{\epsilon_{2,3}} = \delta_{\epsilon_{3,2}} = \delta_{\epsilon_{3,2}} = \delta_{\epsilon_{3,3}} \)) (E, F) with \( \sigma_4 = 1.1 \text{ S m}^{-1}, \epsilon_4 = 0.9 \times 10^5 \) (dimensionless). Relative resistance and reactance errors changing the admittivity of domain \( \Omega_4 \) (i.e., \( \delta_{\sigma_4}, \delta_{\epsilon_4} \)) (G, H) with \( \sigma_{[2,3]} = 1.1 \text{ S m}^{-1}, \epsilon_{[2,3]} = 0.9 \times 10^5 \) (dimensionless). Additional simulation setting parameters: \( \sigma_1 = 1 \text{ S m}^{-1}, \epsilon_2 = 1 \times 10^5 \) (dimensionless), \( h_1 = 2 \text{ mm}, l_{[2,3]} = 8 \text{ mm}, b_{[2,3]} = 3 \text{ mm}, \theta_C^{[2,3]} = 45^\circ \).
Figure 17. Analytical and FEM-simulated impedance results of case study 5 (see Figure 12 E). Theoretical (solid line) and FEM-simulated (dotted line) resistance and reactance with \( h_1 = [1, 5] \) mm, \( l_{(2.3)} = 8 \) mm, \( b_{(2.3)} = 2 \) mm, \( \theta_{C_{(2.3)}} = 70^\circ \) (A); \( b_3 = [2, 6] \) mm, \( b_3 = 4 \) mm, \( l_{(2.3)} = 10 \) mm, \( \theta_{C_{(2.3)}} = 45^\circ \) (B); \( l_2 = [6, 14] \) mm, \( l_3 = 7 \) mm, \( h_1 = 1 \) mm, \( b_{(2.3)} = 3 \) mm, \( \theta_{C_{(2.3)}} = 45^\circ \) (C); \( \theta_{C_2} = [40^\circ, 60^\circ], \theta_{C_3} = 45^\circ, l_{(2.3)} = 7 \) mm, \( b_{(2.3)} = 3 \) mm (D).

Additional simulation setting parameters: \( \sigma_1 = 1 S m^{-1}, \varepsilon_{\ell_2} = 1 \times 10^5 \) (dimensionless), \( \sigma_2 = 1.1 S m^{-1}, \varepsilon_{\ell_2} = 1.1 \times 10^5 \) (dimensionless), \( \sigma_3 = 0.9 S m^{-1}, \varepsilon_{\ell_3} = 0.9 \times 10^5 \) (dimensionless), \( \sigma_4 = 0.95 S m^{-1}, \varepsilon_{\ell_4} = 1.05 \times 10^5 \) (dimensionless). Relative resistance and reactance errors changing the admittivity of domain \( \Omega_{(2.3)} \) (i.e., \( \delta_{\sigma_{2.3}} = \delta_{\varepsilon_{\ell_2}}, \delta_{\sigma_{2.3}} = \delta_{\varepsilon_{\ell_3}} \)) (E, F) with \( \sigma_3 = 1.1 S m^{-1}, \varepsilon_{\ell_4} = 0.9 \times 10^5 \) (dimensionless). Relative resistance and reactance errors changing the admittivity of domain \( \Omega_4 \) (i.e., \( \delta_{\sigma_4}, \delta_{\varepsilon_4} \)) (G, H) with \( \sigma_{(2.3)} = 1.1 S m^{-1}, \varepsilon_{(2.3)} = 0.9 \times 10^5 \) (dimensionless). Additional simulation setting parameters: \( \sigma_1 = 1 S m^{-1}, \varepsilon_{\ell_2} = 1 \times 10^5 \) (dimensionless), \( h_1 = 2 \) mm, \( l_{(2.3)} = 8 \) mm, \( b_{(2.3)} = 3 \) mm, \( \theta_{C_{(2.3)}} = 45^\circ \).
properties of spherical volumes are $< 0.5\%$ for case study 4 (Figure 16 E, F) and $\leq 0.2\%$ for case study 5 (Figure 17 E, F). If we consider changes in the conductivity and relative permittivity properties of the two-layered tissues, then the maximum errors are $< 8\%$ for case study 4 (Figure 16 G, H) and $< 0.08\%$ for case study 5 (Figure 17 G, H). We note that case study 5 in full space has better model accuracy than half-space in case study 4.

9. Discussion

9.1. Nonhomogeneous multi-domain and isotropic framework in half and full space

This paper proposes a novel physics-driven framework for modeling electrical bioimpedance measurements of nonhomogeneous tissue considering both conductivity and relative permittivity properties of tissues along with their frequency dependence. Our theoretical framework can be used to model both surface and needle measurement of nonhomogeneous tissue with arbitrary shape considering series, parallel, and series-parallel circuit-like topologies. In these topologies, we first determine the electrical potential distribution within the model, the (approximated) apparent impedance and finally its sensitivity to changes in tissue electrical properties. For each topology, we confirm the usefulness of our framework performing numerical and FEM simulations considering up to 5 case studies. In summary, the simulation results reveal a maximum resistance and reactance error of $< 4\%$ and $< 8\%$, respectively.

9.2. Comparison to previous literature
Table 3. Review of nonhomogeneous theoretical studies published in the literature sorted by year of publication. Notation: $\sigma \in \mathbb{R}$, conductivity; $\rho \in \mathbb{R}$, resistivity; $\gamma \in \mathbb{C}$, admittivity; $\mathbb{R}^3$, half space; $\mathbb{R}^3$, full space; $Z \in \mathbb{C}$, impedance.

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<th>Model input</th>
<th>Model output</th>
<th>Impedance sensitivity</th>
<th>Application</th>
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<td>Direct current</td>
<td>Apparent $\rho$</td>
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<td>(Lyde 1982)</td>
<td>Isotropic $\rho$</td>
<td>2</td>
<td>Sphere in $\mathbb{R}^3$</td>
<td>Implanted, point-like</td>
<td>Alternating current</td>
<td>Electrical potential</td>
<td>N.A.</td>
<td>Geophysics</td>
</tr>
<tr>
<td>(Wilson et al. 1985)</td>
<td>Anisotropic $\sigma$</td>
<td>4</td>
<td>Nested cylinders in $\mathbb{R}^3$</td>
<td>N.A.</td>
<td>Electrical potential</td>
<td>Electrical potential</td>
<td>N.A.</td>
<td>Biophysics</td>
</tr>
<tr>
<td>(Ganapathy &amp; Clark 1987)</td>
<td>Isotropic $\sigma$</td>
<td>2</td>
<td>Cylinders in $\mathbb{R}^3$</td>
<td>Nerve, cylindrical surface</td>
<td>Transmembrane current</td>
<td>Electrical potential</td>
<td>N.A.</td>
<td>Biophysics</td>
</tr>
<tr>
<td>(Ganapathy et al. 1987)</td>
<td>Anisotropic $\sigma$</td>
<td>3</td>
<td>Nested cylinders in $\mathbb{R}^3$</td>
<td>N.A.</td>
<td>Electrical potential</td>
<td>Electrical potential</td>
<td>N.A.</td>
<td>Biophysics</td>
</tr>
<tr>
<td>(Altman &amp; Plonsey 1988)</td>
<td>Anisotropic $\sigma$</td>
<td>2</td>
<td>Cylinder in $\mathbb{R}^3$</td>
<td>Implanted, point-like</td>
<td>Transmembrane current</td>
<td>Electrical potential</td>
<td>N.A.</td>
<td>Biophysics</td>
</tr>
<tr>
<td>(Altman &amp; Plonsey 1990)</td>
<td>Anisotropic $\sigma$</td>
<td>2</td>
<td>Sphere in $\mathbb{R}^3$</td>
<td>Cardiac, spherical shell</td>
<td>Transmembrane current</td>
<td>Electrical potential</td>
<td>N.A.</td>
<td>Biophysics</td>
</tr>
<tr>
<td>(Roth 1997)</td>
<td>Anisotropic $\sigma$</td>
<td>2</td>
<td>Two-dimensional media in $\mathbb{R}^3$</td>
<td>Implanted, point-like</td>
<td>Steady state current</td>
<td>Electrical potential</td>
<td>N.A.</td>
<td>Biophysics</td>
</tr>
<tr>
<td>(Vickery &amp; Hobbs 2002)</td>
<td>Isotropic $\rho$</td>
<td>2</td>
<td>Cylinder in $\mathbb{R}^3$</td>
<td>Surface, point-like</td>
<td>Steady state current</td>
<td>Apparent $\rho$</td>
<td>No</td>
<td>Geophysics</td>
</tr>
<tr>
<td>(Joshu &amp; Song 2010)</td>
<td>Isotropic $\gamma$</td>
<td>3</td>
<td>Nested Cylinders in $\mathbb{R}^3$</td>
<td>Implanted, point-like</td>
<td>Pulsed current</td>
<td>Electrical potential</td>
<td>N.A.</td>
<td>Biophysics</td>
</tr>
<tr>
<td>(Ness et al. 2015)</td>
<td>Anisotropic $\sigma$</td>
<td>2</td>
<td>Cylinder in Two-layered volume in $\mathbb{R}^3$</td>
<td>Implanted, point-like</td>
<td>Alternating current</td>
<td>Electrical potential</td>
<td>N.A.</td>
<td>Biophysics</td>
</tr>
<tr>
<td>(Schwartz &amp; Sadleir 2015)</td>
<td>Isotropic $\rho$</td>
<td>2</td>
<td>Sphere in $\mathbb{R}^3$</td>
<td>Implanted, point-like</td>
<td>Alternating current</td>
<td>Electrical potential</td>
<td>N.A.</td>
<td>Biophysics</td>
</tr>
<tr>
<td>(Schwartz et al. 2016)</td>
<td>Isotropic $\sigma$</td>
<td>2</td>
<td>Cylinder in $\mathbb{R}^3$</td>
<td>Implanted, point-like</td>
<td>Stimulating current</td>
<td>Electrical potential</td>
<td>N.A.</td>
<td>Biophysics</td>
</tr>
<tr>
<td>(Nem 2016)</td>
<td>Isotropic $\gamma$</td>
<td>$\geq 2$</td>
<td>Arbitrary series, parallel, series-parallel in $\mathbb{R}^3$ and $\mathbb{R}^3$</td>
<td>Surface/Implanted, point-like</td>
<td>Alternating current</td>
<td>Electrical potential, apparent Z</td>
<td>Yes</td>
<td>Biophysics</td>
</tr>
</tbody>
</table>

This study Isotropic $\gamma$ $\geq 2$ Arbitrary series, parallel, series-parallel in $\mathbb{R}^3$ and $\mathbb{R}^3$ Surface/Implanted, point-like Alternating current Electrical potential, apparent Z Yes Biophysics
To put the novelty and contribution of our work in context, we provide in Table 3 a review of studies published in the literature where the authors developed theoretical frameworks for modeling nonhomogeneous media. Table 3 shows that a large number of studies were developed to determine the electrical potential measured caused by transmembrane current, e.g., due to membrane depolarization (Clark & Plonsey 1966, Clark & Plonsey 1968, Clark & Plonsey 1970). These studies focused on modeling the propagation of the electrical potential generated for example in a cylindrical nerve cell, and propagated through the surrounding bulk of (anisotropic) muscle, subcutaneous fat and skin and then finally recorded with a distant electrode from the source (Altman & Plonsey 1988, Altman & Plonsey 1990). These studies were essential to understand the low-pass frequency filtering effects affecting the morphology of extracellular potentials introduced by intermediate tissue between the source of current and a distant voltage recording electrode. Subsequently, the number of domains considered is not more than 4 with cylindrical geometry in order to model the anatomical shape of a limb for example. Although not related to physiological measurement, a review of the literature would be incomplete without including nonhomogeneous models developed in the field of geophysical surveying for soil determination. In this particular application, models developed were primarily based on soil resistivity for applications including ore detection (Lytle 1982).

It is also worth noting that in most studies, regardless of the directionality of electrical properties, the only conduction effect considered is purely ohmic through the resistivity (or its inverse, the conductivity, if the relative permittivity is ignored). To the best of the authors’ knowledge, we are only aware of one previous study where the authors considered both the conductivity and the relative permittivity (i.e., the admittivity) in the propagation of the electrical potential in a cylindrical domain (Joshi & Song 2010), however, our framework is more general in the sense that it can model any parameterizable geometry. By considering the admittivity, we not only provide an approximated analytical expression of the electric potential but also an approximate analytical expression for the apparent impedance including the imaginary part (i.e., the reactance). Compared to existing literature, our framework is general enough to model an arbitrary number of domains. This may help to get insight not currently available in emerging bioimpedance applications in which there is not a cylindrical tissue geometry, for example, a localized bioimpedance measure of pulsatile blood flow on the wrist (Kusche et al. 2018) or neck (Shen et al. 2019) for the next generation of wearable devices.

Unlike studies where the authors solved the Poisson’ equation considering a specific nonhomogeneous geometry (Lee 1975, Altman & Plonsey 1990), the gist of our approach to solve a generic nonhomogeneous topology lies in using an iterative approximation strategy. In doing so, we were able to obtain a general bioimpedance expression for nonhomogeneous tissue separating the contribution of the domains’ electrical property, the electrodes geometry, and domain geometry. This allowed us to provide an analytical expression for the sensitivity to electrical changes in individual domains within the nonhomogeneous tissue, which has not been done before. This is especially relevant because it allows the user to predict the impedance change due to a change in internal conductivity in one of the domains within the nonhomogeneous tissue. Finally, our modeling approach allowed us to interpret
nonhomogeneous tissue with electrical circuit equivalents such as series, parallel and series-parallel, introducing a novel theoretical concept that also has never been applied before and which raises further questions, discussed below.

9.3. Comparison to other bioimpedance modeling approaches

There exist three modeling approaches to interpret nonhomogeneous bioimpedance illustrated in Figure 18: physics-driven models, computational models and equivalent electrical circuit models. Unlike FEM only and circuit-based approaches, the theoretical approach presented provides a general and structured framework to describe macroscopically nonhomogeneous bioimpedance measurement directly relating electrodes, domain and tissue electrical properties. As any theoretical study, assumptions are necessary to solve the governing equations analytically such as considering the domain (semi-)infinite. FEM modeling approaches would be helpful to further investigate the accuracy of our theoretical predictions when these assumptions are not met, for example, modeling a finite-shape domain. Modeling bioimpedance using equivalent circuits is, compared to our approach and FEM methods, fundamentally different. In this case, data is described by empirical circuits which is valuable for simplifying the complex nature originating bioimpedance data using a circuital parameter of interest.

Figure 18. Flow diagram showing the approaches available for model bioimpedance. In this work we have followed steps 1 to 6.
Figure 19. (A) Schematic representing the nonhomogeneous tissue with intersecting domains \( \Omega_i, i \in \{1, \cdots, 5\} \). (B) Schematic illustrating a nonhomogeneous impedance measurement with current and voltage electrodes in different domains. The outer two electrodes are the high (source) and low (sink) current electrodes, whereas the inner electrodes are the high and low potential recording electrodes.

9.4. Limitations

This study has important limitations that are worth highlighting. First, modeling nonhomogeneous tissue with \emph{series}, \emph{parallel} and \emph{series-parallel} circuit-like topologies is a simplification that does not describe all possible nonhomogeneities. Albeit general, it cannot model a nonhomogeneous tissue consisting of the intersection between different domains shown in Figure 19 A. Second, the electrodes are assumed to be in contact with just one (i.e., the same) domain within the nonhomogeneous tissue. Further research is necessary to extend the framework to model an arbitrary positioning of the electrodes in different domains with different admittivity properties or even on the boundary between domains (Figure 19 B). Third, the framework is developed assuming the electrodes are placed on a planar surface. This might not be possible to achieve in practice, especially in curved surfaces such as the wrist. Fourth, we considered all domains to have isotropic admittivity properties. In tissues like skeletal muscle, the admittivity has different values along and perpendicular to the muscle fiber, a concept known as electrical anisotropy (Kwon, Guasch, Nagy, Rutkove & Sanchez 2019). Fifth, the framework was developed considering point-like source and electrodes, a more realistic approach would required to consider their finite-size.

9.5. Future directions

We foresee three different future directions stemming from the current work:

(i) Extend the forward framework to model a nonhomogeneous tissue with intersecting domains, arbitrary electrode positioning, anisotropic electrical properties, and finite-size electrodes geometry.

(ii) Develop inverse models to estimate the electrical properties from nonhomogeneous tissue bioimpedance measurements.

(iii) Apply the framework to model non-invasive and penetrating needle bioimpedance measurements of nonhomogeneous tissues. Two examples are surface electrical impedance myography applications to model the effect of intermediate tissues such as the skin and subcutaneous fat tissues affecting muscle readings, and wearable impedance cardiography measurements to disentangle the source of electrical conductivity...
A framework for modeling bioimpedance measurements of nonhomogeneous tissues originating changes in thoracic bioimpedance measurements.

10. Conclusions

Our work provides new scientific insight to model bioimpedance measurements of nonhomogeneous tissues. This framework might find use for interpreting bioimpedance measurements in multi-domain nonhomogeneous tissues with arbitrary boundary surfaces in half and full space considering both the conductivity and the relative permittivity properties. Simple analytical expressions validated by FEM simulations are also provided for 5 particular case studies considering spherical and multi-layer tissues. Ultimately, this knowledge will help to aid the development of more accurate bioimpedance devices and shed light on the interpretation of bioimpedance results in a multitude of health-related monitoring applications.

Conflict of interest statement

Dr. Sanchez has equity and serves a consultant and scientific advisor to HaystackDx, Inc. and IONIQ Sciences, Inc. He also serves as scientific advisor to B-Secur, Ltd. Dr. Sanchez serves as a consultant to Myolex, Inc., Impedimed, Inc., Texas Instruments, Inc., Happy Health, Inc., companies that develop impedance related technology for consumer, research and clinical use. HaystackDx and Myolex have an option to license patented impedance technology of which Dr. Sanchez is named as an inventor. Impedimed has patented impedance technology of which Dr. Sanchez is named an inventor. This study did not employ any relevant company technology.

Acknowledgments

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Supplementary information for “A framework for modeling bioimpedance measurements in nonhomogeneous tissues: a theoretical and simulation study”

1 Lemma 1.

If \( \partial \Omega_i \) is a spherical surface centered at \( C_i \) with radius \( b_i \) in \( \mathbb{R}^3 \), \( Q_i \) is an arbitrary point on \( \partial \Omega_i \), \( n_i \) is the outward normal vector at \( Q_i \), and \( E \) and \( S \) are arbitrary points outside the sphere as shown in Figure A1, then

\[
-\frac{1}{2\pi} \int_{\partial \Omega_i} \nabla_R \cdot \left( \frac{1}{R_{SQ_i}} \right) \frac{\partial R_{SQ_i}(r_{Q_i})}{\partial n_i} \right) \cdot n_i \frac{d(\partial \Omega_i)}{R_{SQ_i}(r_{Q_i})} R_{EQ}(r_{Q_i}) = \frac{1}{b_i^2} \sum_{n=0}^{\infty} \frac{2n+1}{2n+1} \left( \frac{b_i^2}{R_{SC_i}} \right)^{n+1} P_n(\cos \theta_i).
\] (A1)

**Proof.** To calculate the surface integrals in (A1) we build an auxiliary model of charged spherical shell in vacuum that allows us to find the solution indirectly. Let’s start establishing a spherical coordinates in \( \mathbb{R}^3 \) originated at the center \( C_i \) of the spherical surface \( \partial \Omega_i \) (see Figure A1). The position \( r := (r, \theta, \varphi) \) is an arbitrary defined in spherical coordinates. For convenience, we consider \( S \) with coordinates \( r_S := (R_{SC_i}, 0, 0) \) on the \( z \)-axis, while \( E \) is defined with coordinates \( r_E := (R_{EC_i}, \theta_i, 0) \), while \( Q_i \) with coordinates \( r_{Q_i} := (b_i, \theta_Q, \varphi_Q) \) is an arbitrary point on \( \partial \Omega_i \). \( R_{SC_i} \) is the distance between \( S \) and \( C_i \); \( R_{EC_i} \) is the distance between \( E \) and \( C_i \); \( R_{SQ_i} \) is the distance between \( S \) and \( Q_i \); \( R_{EQ} \) is the distance between \( E \) and \( Q_i \); \( \theta_i \) is the angle between line segment \( |SC_i| \) and \( |EC_i| \); \( \theta_Q \) is the angle between line segment \( |QC_i| \) and \( |SC_i| \). Next, we introduce a charge density function \( q(r_{Q_i}) \in \mathbb{R} \) (C m\(^{-2} \)) on the spherical surface \( \partial \Omega_i \), defined as

\[
q(r_{Q_i}) := \frac{\partial R_{SQ_i}(r_{Q_i})}{\partial n_i} \cdot n_i \left. \frac{1}{R_{SQ_i}(r_{Q_i})} \right| \nabla_R \cdot \left( \frac{1}{R_{SQ_i}(r_{Q_i})} \right) \nabla_R \cdot \left( \frac{1}{R_{EQ}(r_{Q_i})} \right) \nabla_R \cdot \left( \frac{1}{R_{SC_i}} \right)
\]

Then the potential distribution \( U(r) \) caused by \( Q_i \) can be expressed as

\[
U(r) = \frac{1}{4\pi \varepsilon_0} \int_{\partial \Omega_i} \nabla_R \cdot \left( \frac{1}{R_{SQ_i}(r_{Q_i})} \right) \cdot n_i \frac{1}{R_{SQ_i}(r_{Q_i})} \cdot \frac{d(\partial \Omega_i)}{R_{SQ_i}(r_{Q_i})} \cdot \frac{1}{|\mathbf{r} - r_{Q_i}|}.
\] (A2)

According to the axial symmetry, \( U \) has no dependence on the azimuthal angle \( \varphi \). Then applying separation of variables to Poisson’s equation, the general solution for potential distribution \( U(r) \) in spherical coordinates satisfies that

\[
U(r) = \sum_{n=0}^{\infty} \left( A_n r^n + \frac{B_n}{r^{n+1}} \right) P_n(\cos \theta),
\] (A3)

where \( A_n \) and \( B_n \) are a series of constants and \( P_n(x) \) are Legendre polynomials.
In this model, an auxiliary point $E'$ with coordinates $r_{E'} := (R_{EC}, 0, 0)$ is introduced to solve the surface integral (A2) indirectly, which satisfy $|E'C| = |EC|$ and $E'$ is on $z$-axis. From (A3), the potential at $E'$ can be written as

$$U(r_{E'}) = \sum_{n=0}^{\infty} \left( A_n R_{EC}^n + \frac{B_n}{R_{EC}^{n+1}} \right).$$  

(A4)

From (A2), $V(r_{E'})$ can also be expressed as

$$U(r_{E'}) = \frac{1}{4\pi\varepsilon_0} \int_{-\pi}^{\pi} \int_{0}^{\pi} \frac{\partial R_{SQ}(r_{Q_i})}{\partial b_i} \frac{b_i^2 \sin \theta_{Q_i}}{R_{SQ}(r_{Q_i})R_{Q_i}E'(r_{Q_i})},$$  

(A5)

where

$$R_{SQ}(r_{Q_i}) = \sqrt{R_{SC}^2 + b_i^2 - 2b_iR_{SC}\cos \theta_{Q_i}},$$

and

$$R_{Q_iE'}(r_{Q_i}) = \sqrt{R_{EC}^2 + b_i^2 - 2b_iR_{EC}\cos \theta_{Q_i}}.$$

Equation (A5) can be further simplified as

$$U(r_{E'}) = \frac{1}{4\pi\varepsilon_0} \left[ \frac{2b_i}{b_i^2 - R_{EC}R_{SC}} + \frac{1}{\sqrt{R_{EC}R_{SC}}} \ln \left( \frac{\sqrt{R_{EC}R_{SC}} + b_i}{\sqrt{R_{EC}R_{SC}} - b_i} \right) \right].$$  

(A6)
From the geometry of the model, we have that \( \frac{b_i}{\sqrt{R_{EC} R_{SC}}} < 1 \). According to Taylor series we have

\[
\ln \left( \frac{\sqrt{R_{EC} R_{SC}} + b_i}{\sqrt{R_{EC} R_{SC}} - b_i} \right) = \sum_{n=0}^{\infty} \frac{1}{n} \frac{b_i^n}{R_{EC} R_{SC}^{n+1}} + \sum_{n=1}^{\infty} \frac{(-1)^{n+1} b_i^n}{n R_{EC}^{n+1}} R_{SC}^{n+1}.
\]

(A7)

Substituting (A7) into (A6) gives

\[
U(\mathbf{r}_E') = -\frac{1}{b_i e_0} \sum_{n=0}^{\infty} \frac{n}{2n+1} \left( \frac{b_i^2}{R_{EC} R_{SC}} \right)^n.
\]

(A8)

Comparing (A8) and (A4), we have

\[
\begin{cases}
A_n = 0 \\
B_n = -\frac{1}{e_0} \frac{nb_i^{2n+1}}{(2n+1)R_{SC}^{n+1}}.
\end{cases}
\]

(A9)

Substituting (A9) to (A3) gives

\[
U(\mathbf{r}) = -\frac{1}{e_0} \sum_{n=0}^{\infty} \frac{nb_i^{2n+1}}{(2n+1)R_{SC}^{n+1}} \frac{1}{R_{EQ}^2} P_n(\cos \theta).
\]

(A10)

Then the potential at \( E \) is

\[
U(\mathbf{r}_E) = -\frac{1}{b_i e_0} \sum_{n=0}^{\infty} \frac{n}{2n+1} \left( \frac{b_i^2}{R_{EC} R_{SC}} \right)^n P_n(\cos \theta).
\]

(A11)

According to (A2), \( U(\mathbf{r}_E) \) can also be written as

\[
U(\mathbf{r}_E) = \frac{1}{4 \pi e_0} \int_{\partial \Omega} \frac{\partial R_{EQ}(\mathbf{r}_Q)}{\partial \mathbf{n}_i} \cdot \mathbf{n}_i \frac{d(\partial \Omega_i)}{R_{EQ}^2(\mathbf{r}_Q) R_{EQ}(\mathbf{r}_Q)}.
\]

(A12)

One can find (A1) equating the right hand sides of (A11) and (A12).

\[\square\]

2 Lemma 2.

If \( \partial \Omega \) is an infinity plane in \( \mathbb{R}^3 \), \( Q_i \) is an arbitrary point on \( \partial \Omega \), and \( S, E \) are arbitrary points share the same distance \( N_i \) to plane \( \partial \Omega \), as shown in Figure B1, then

\[
-\frac{1}{2 \pi} \int_{\partial \Omega_i} \frac{\partial R_{EQ}(\mathbf{r}_Q)}{\partial \mathbf{n}_i} \cdot \mathbf{n}_i \frac{d(\partial \Omega_i)}{R_{EQ}^2(\mathbf{r}_Q) R_{EQ}(\mathbf{r}_Q)} = \frac{1}{\sqrt{R_{SE}^2 + 4N_i^2}}.
\]

(B1)
Figure B1: Auxiliary model of charged plane $\partial \Omega_i : z = -N_i$ in vacuum. The position $Q_i$ has coordinates $r_{Q_i} := (x, y, -N_i)$ is an arbitrary point on the plane. The charge density $q(r_{Q_i})$ is distributed on $\partial \Omega_i$. Positions $S$, $E$ and $E'$ have coordinates $r_{S} := (0, 0, 0)$, $r_{E} := (0, R_{SE}, 0)$ and $r_{E'} := (0, 0, R_{SE})$ in the vacuum, which satisfy the line segments $|ES| = |E'S|$.

**Proof.** We follow a similar procedure as we did in Lemma 1. First, we establish a Cartesian coordinates $(x, y, z)$ in $\mathbb{R}^3$ with origin $S$ at $r_{S} := (0, 0, 0)$. We then place $E$ at $r_{E} := (0, R_{SE}, 0)$ on the $y$-axis and $\partial \Omega_i$ as the normal plane of $z$-axis. The position $Q_i$ is defined with coordinates $r_{Q_i} := (x, y, -N_i)$ on the plane $\partial \Omega_i : z = -N_i$. $R_{SE}$ is the distance between $S$ and $E$. Next, we introducing the same charge density distribution function $q(r_{Q_i})$ on the plane $\partial \Omega_i$ as in Lemma 1. According to (A2), $U(r_{E'})$ can be expressed as

$$U(r_{E'}) = \frac{1}{4\pi \varepsilon_0} \int_{-\infty}^{\infty} \int_{-\infty}^{\infty} -\frac{\partial R_{SO}(r_{Q_i})}{\partial N_i} \frac{dxdy}{R_{SO}^2(r_{Q_i}) R_{Q'EO}(r_{Q_i})},$$

(B2)

where

$$R_{SO}(r_{Q_i}) = \sqrt{x^2 + y^2 + N_i^2},$$

and

$$R_{Q'EO}(r_{Q_i}) = \sqrt{x^2 + y^2 + (R_{SE} + N_i)^2}.$$

Then, (B2) can be simplified as

$$U(r_{E'}) = -\frac{1}{4\pi \varepsilon_0} \frac{1}{2N_i + R_{SE}}.$$

(B3)

Equation (B3) can be rewritten using Taylor series as

$$U(r_{E'}) = \begin{cases} 
-\frac{1}{4\pi \varepsilon_0} \sum_{n=0}^{\infty} \frac{(-1)^n 2^n N_i^n}{R_{SE}^{n+1}} & \text{if } 2N_i < R_{SE} \\
-\frac{1}{4\pi \varepsilon_0} \sum_{n=0}^{\infty} \frac{(-1)^n 2^n R_{SE}^n}{2^{n+1} N_i^{n+1}} & \text{if } 2N_i > R_{SE}.
\end{cases}$$

(B4)
Comparing (B4) with (A3) we have

\[
\begin{cases}
    A_n = 0, B_n = -\frac{1}{2\varepsilon_0} (-1)^n 2^n N_i^n & \text{if } 2N_i < R_{SE} \\
    A_n = -\frac{1}{2\varepsilon_0} (-1)^n 2^{n+1} N_i^{n+1}, B_n = 0 & \text{if } 2N_i > R_{SE}.
\end{cases}
\]  

(B5)

The position \( r_E \) can also be re-written as \((R_{SE}, \pi/2, 0)\) in spherical coordinates. Substituting (B5) into (A3) then gives

\[
U (r_E) = \begin{cases}
    -\frac{1}{2\varepsilon_0} \sum_{n=0}^{\infty} \frac{(-1)^n 2^n N_i^n}{R_{SE}^{n+1}} P_n(0) & \text{if } 2N_i < R_{SE} \\
    -\frac{1}{2\varepsilon_0} \sum_{n=0}^{\infty} \frac{(-1)^n 2^n N_i^n}{2^{n+1} N_i^{n+1}} P_n(0) & \text{if } 2N_i > R_{SE}.
\end{cases}
\]

(B6)

Since the Legendre polynomials can be expressed in differential form, namely

\[
P_n(x) = \frac{1}{2^n n!} \frac{d^n}{dx^n} \left[(x^2 - 1)^n\right],
\]

we have that

\[
P_n(0) = \begin{cases}
    \frac{(-1)^n (2m)!}{2^m (m)!^2} & \text{for } n = 2m \\
    0 & \text{for } n = 2m + 1.
\end{cases}
\]  

(B7)

From Taylor series we have

\[
\frac{1}{\sqrt{1+x}} = \sum_{m=0}^{\infty} \frac{(-1)^m (2m)!}{2^m (m)!^2} x^m
\]

when \(|x| < 1\). Substituting (B7) and (B8) into (B6) gives

\[
U (r_E) = -\frac{1}{2\varepsilon_0 \sqrt{R_{SE}^2 + 4N_i^2}}.
\]

(B9)

One can find (B1) equating the right hand sides of (B9) with (A12).